

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: E Device Section

Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Low/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

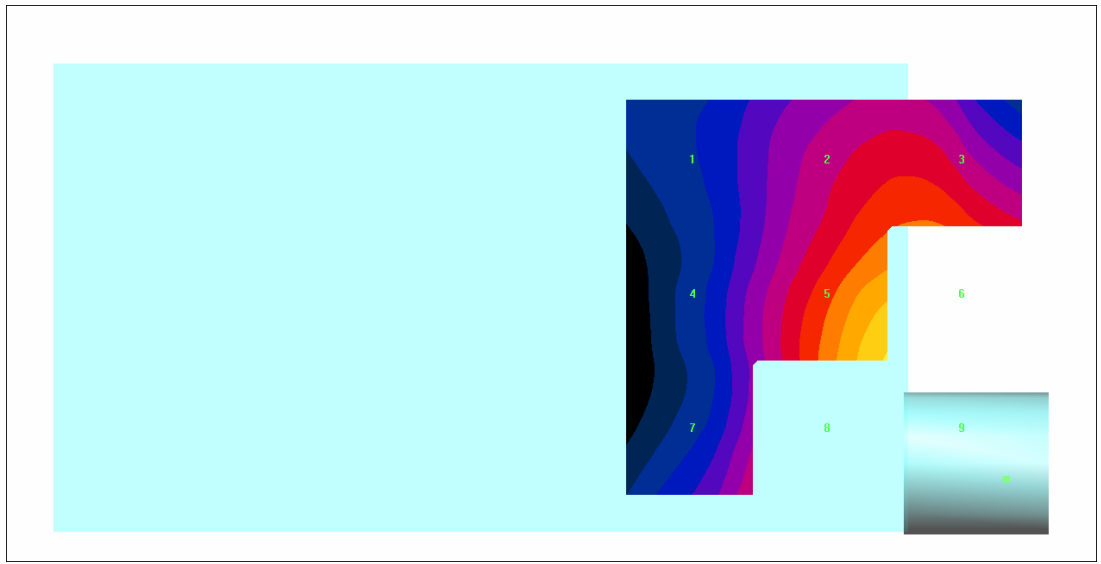
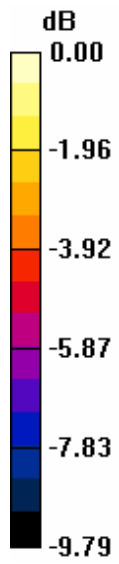
**Maximum value of Total field (slot averaged) = 84.5 V/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>47.4</b>	Grid 2 <b>65.6</b>	Grid 3 <b>67.1</b>	Grid 1 <b>47.7</b>	Grid 2 <b>66.1</b>	Grid 3 <b>67.6</b>
Grid 4 <b>51.0</b>	Grid 5 <b>83.9</b>	Grid 6 <b>89.3</b>	Grid 4 <b>51.4</b>	Grid 5 <b>84.5</b>	Grid 6 <b>90.0</b>
Grid 7 <b>56.2</b>	Grid 8 <b>93.0</b>	Grid 9 <b>103.8</b>	Grid 7 <b>56.7</b>	Grid 8 <b>93.7</b>	Grid 9 <b>104.6</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 103.8V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

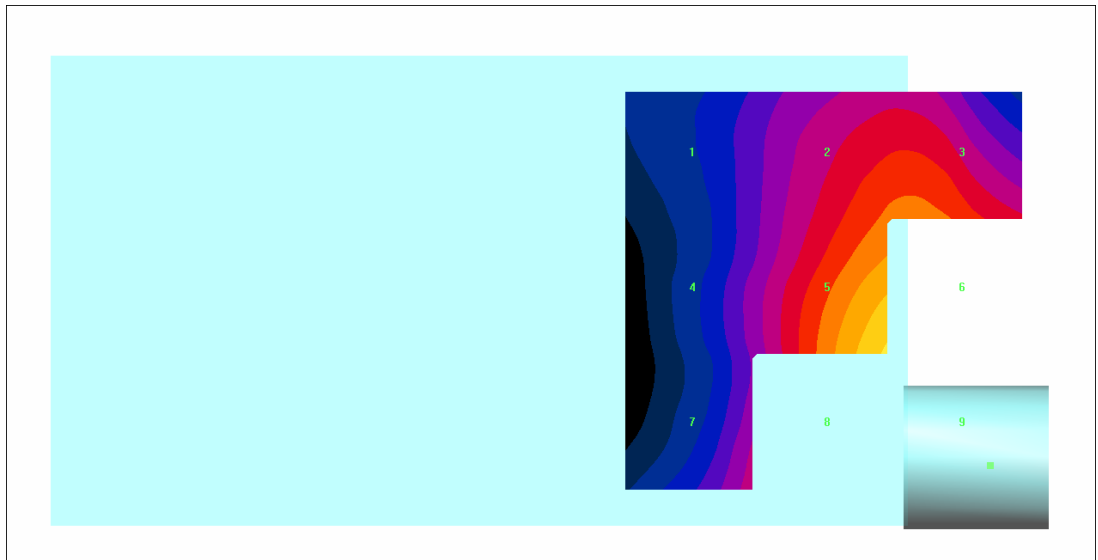
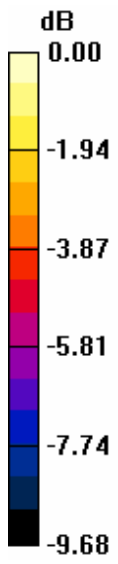
**Maximum value of Total field (slot averaged) = 87.6 V/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>49.7</b>	Grid 2 <b>69.8</b>	Grid 3 <b>71.3</b>	Grid 1 <b>50.1</b>	Grid 2 <b>70.3</b>	Grid 3 <b>71.8</b>
Grid 4 <b>52.7</b>	Grid 5 <b>87.0</b>	Grid 6 <b>92.9</b>	Grid 4 <b>53.1</b>	Grid 5 <b>87.6</b>	Grid 6 <b>93.6</b>
Grid 7 <b>57.4</b>	Grid 8 <b>95.9</b>	Grid 9 <b>106.7</b>	Grid 7 <b>57.8</b>	Grid 8 <b>96.6</b>	Grid 9 <b>107.5</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 106.7V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

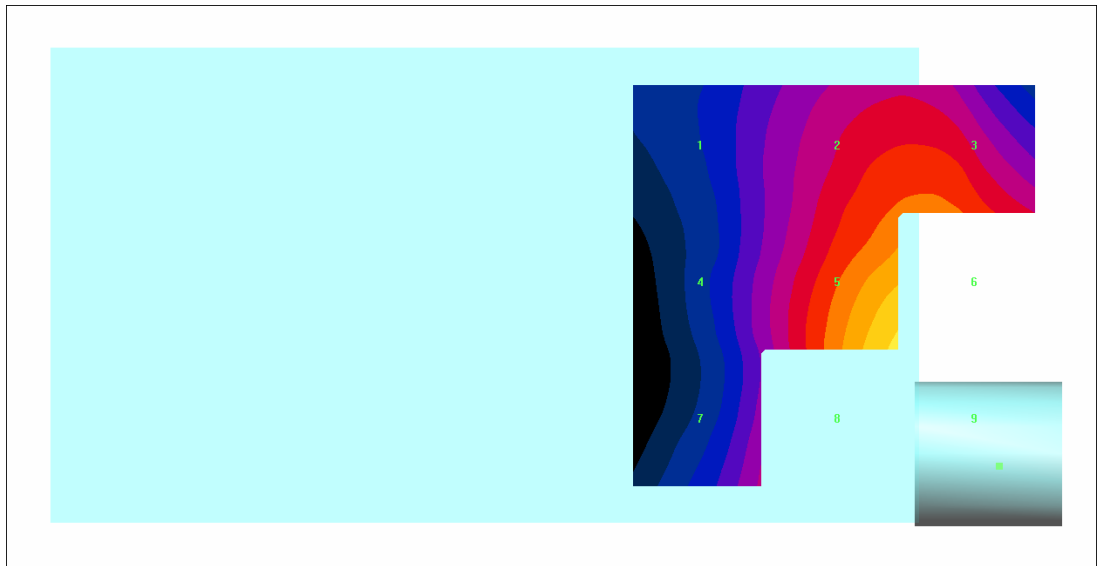
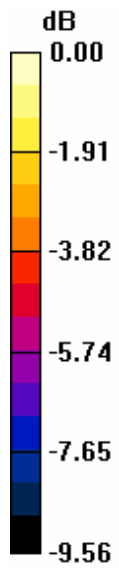
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 87.3 V/m**  
**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>50.6</b>	Grid 2 <b>69.0</b>	Grid 3 <b>70.1</b>	Grid 1 <b>51.0</b>	Grid 2 <b>69.5</b>	Grid 3 <b>70.6</b>
Grid 4 <b>52.8</b>	Grid 5 <b>86.7</b>	Grid 6 <b>92.0</b>	Grid 4 <b>53.2</b>	Grid 5 <b>87.3</b>	Grid 6 <b>92.7</b>
Grid 7 <b>55.5</b>	Grid 8 <b>93.9</b>	Grid 9 <b>105.3</b>	Grid 7 <b>56.0</b>	Grid 8 <b>94.6</b>	Grid 9 <b>106.1</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 105.3V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

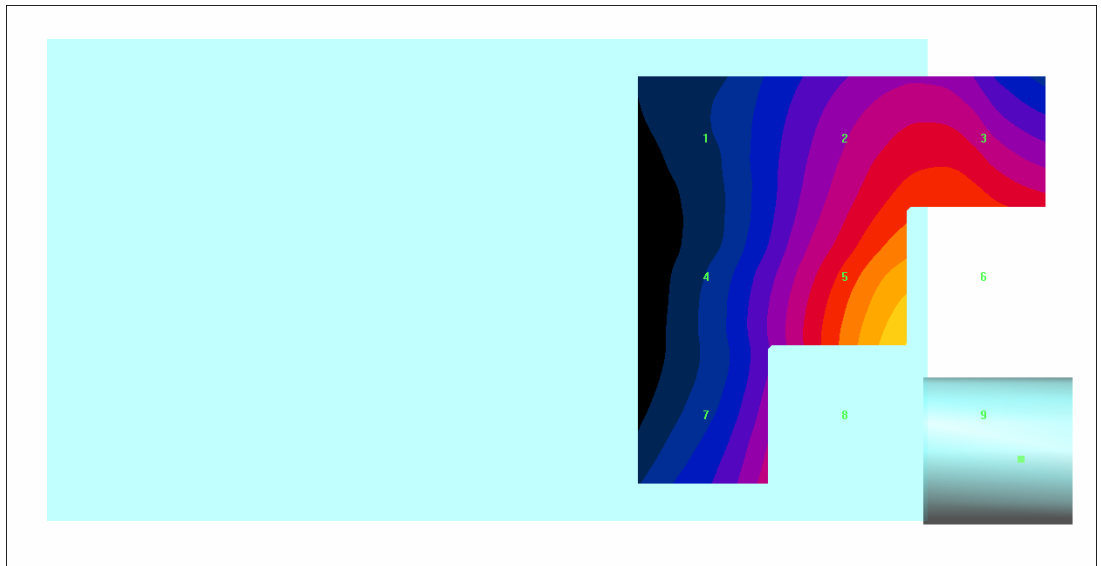
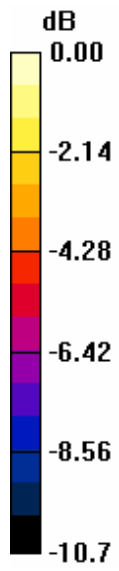
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Low with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 86.2 V/m  
 Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>43.1</b>	Grid 2 <b>64.6</b>	Grid 3 <b>66.6</b>	Grid 1 <b>43.5</b>	Grid 2 <b>65.1</b>	Grid 3 <b>67.1</b>
Grid 4 <b>48.3</b>	Grid 5 <b>85.5</b>	Grid 6 <b>93.7</b>	Grid 4 <b>48.7</b>	Grid 5 <b>86.2</b>	Grid 6 <b>94.4</b>
Grid 7 <b>54.4</b>	Grid 8 <b>94.5</b>	Grid 9 <b>108.8</b>	Grid 7 <b>54.8</b>	Grid 8 <b>95.2</b>	Grid 9 <b>109.6</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 108.8V/m



Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

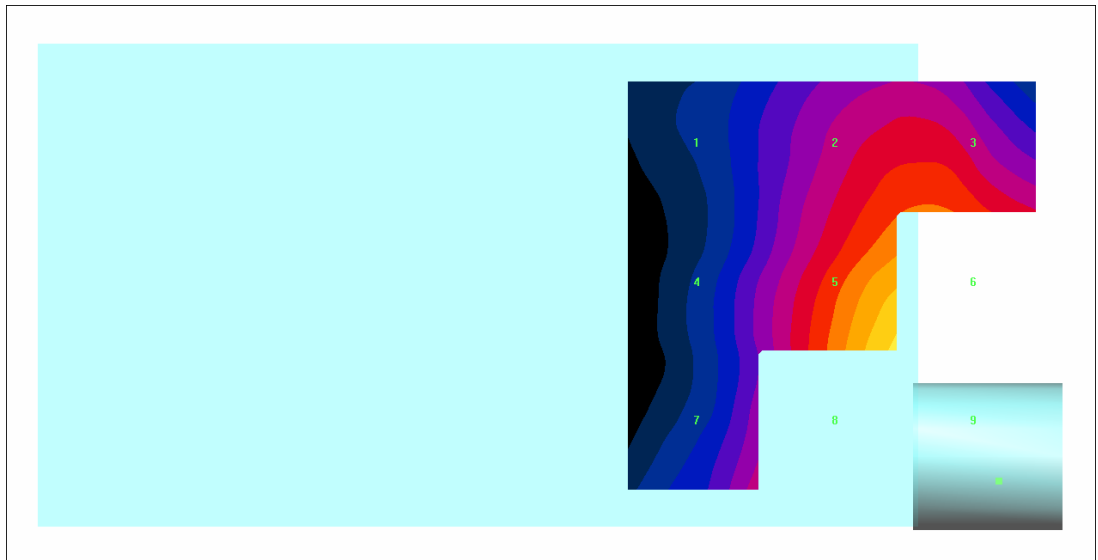
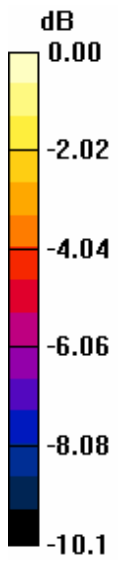
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid with co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 89.7 V/m**  
**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>47.0</b>	Grid 2 <b>68.5</b>	Grid 3 <b>70.1</b>	Grid 1 <b>47.4</b>	Grid 2 <b>69.0</b>	Grid 3 <b>70.6</b>
Grid 4 <b>51.8</b>	Grid 5 <b>89.1</b>	Grid 6 <b>95.2</b>	Grid 4 <b>52.2</b>	Grid 5 <b>89.7</b>	Grid 6 <b>96.0</b>
Grid 7 <b>57.3</b>	Grid 8 <b>97.3</b>	Grid 9 <b>109.7</b>	Grid 7 <b>57.7</b>	Grid 8 <b>98.0</b>	Grid 9 <b>110.6</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 109.7V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

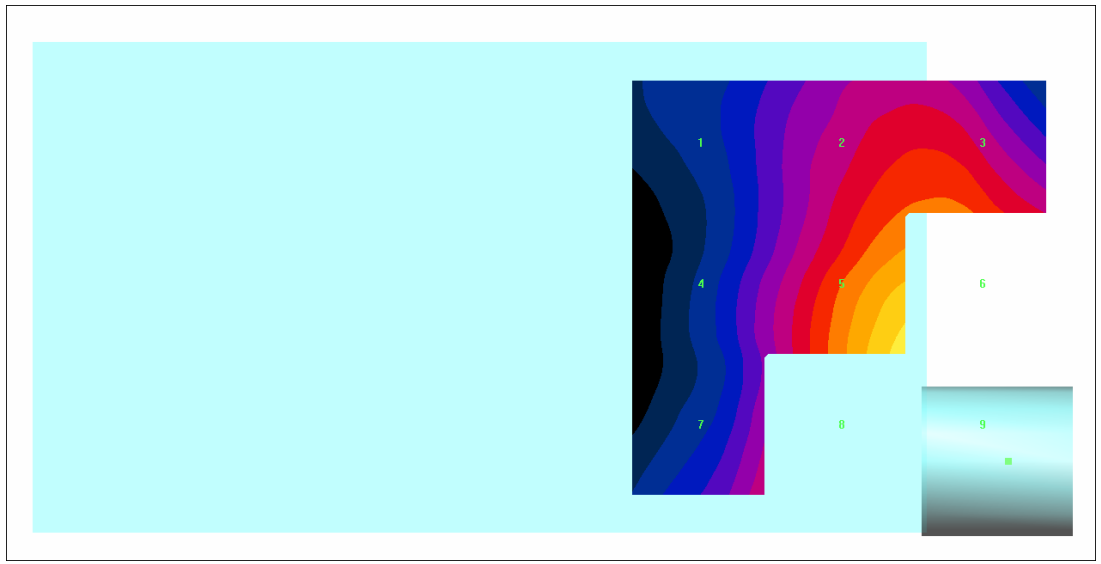
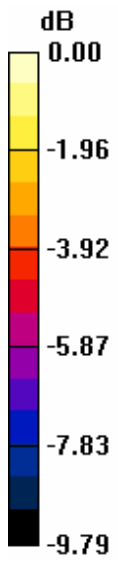
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 87.5 V/m  
 Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>46.9</b>	Grid 2 <b>67.1</b>	Grid 3 <b>68.5</b>	Grid 1 <b>47.2</b>	Grid 2 <b>67.6</b>	Grid 3 <b>69.0</b>
Grid 4 <b>51.3</b>	Grid 5 <b>86.8</b>	Grid 6 <b>92.2</b>	Grid 4 <b>51.7</b>	Grid 5 <b>87.5</b>	Grid 6 <b>92.9</b>
Grid 7 <b>56.1</b>	Grid 8 <b>95.1</b>	Grid 9 <b>104.2</b>	Grid 7 <b>56.5</b>	Grid 8 <b>95.8</b>	Grid 9 <b>105.0</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 104.2V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

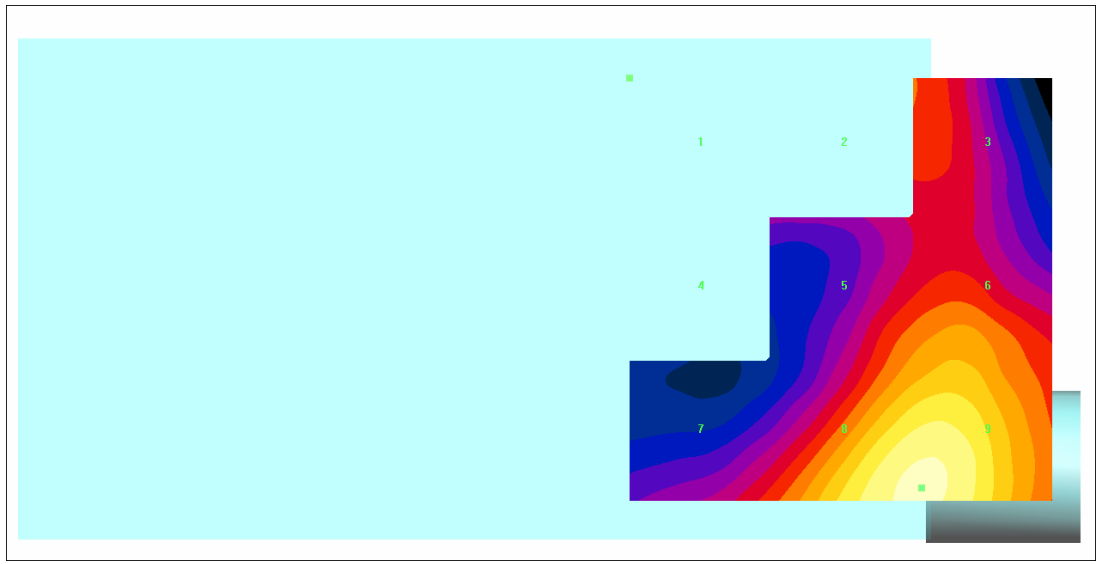
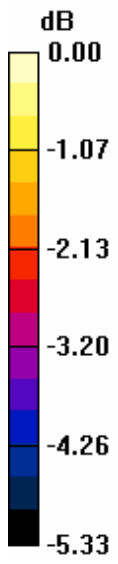
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Low/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 56.9 V/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
58.2	51.5	45.8	58.5	51.7	46.0
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
45.8	47.3	49.3	46.0	47.6	49.6
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
44.3	56.5	56.6	44.5	56.7	56.9

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 58.2V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

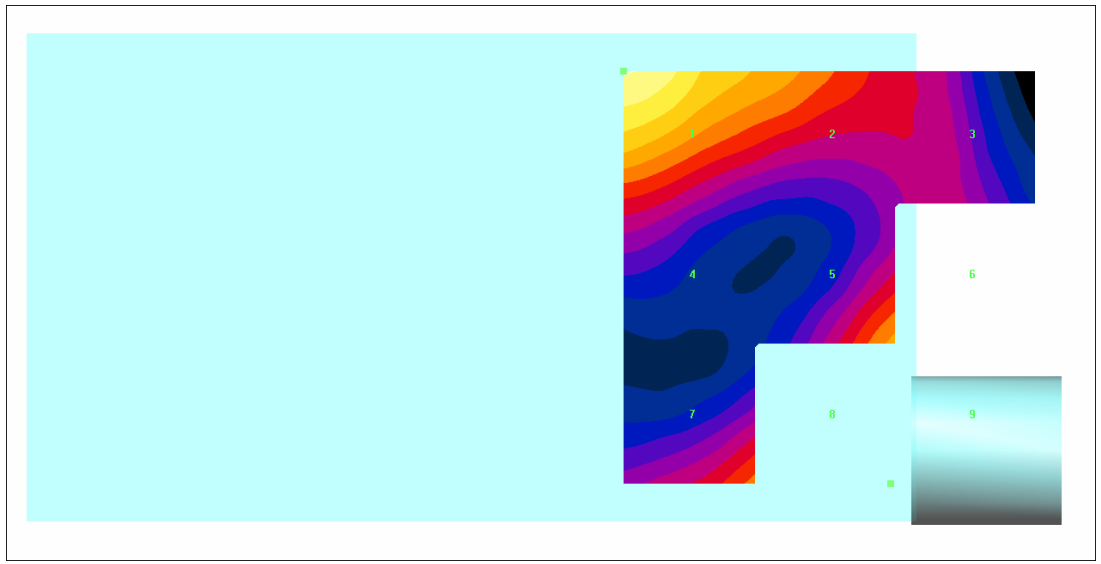
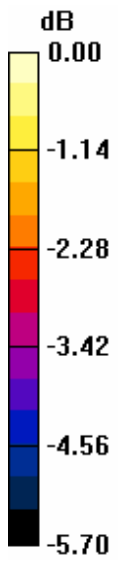
**Maximum value of Total field (slot averaged) = 53.7 V/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>53.4</b>	Grid 2 <b>46.3</b>	Grid 3 <b>40.0</b>	Grid 1 <b>53.7</b>	Grid 2 <b>46.6</b>	Grid 3 <b>40.2</b>
Grid 4 <b>40.0</b>	Grid 5 <b>45.4</b>	Grid 6 <b>47.1</b>	Grid 4 <b>40.2</b>	Grid 5 <b>45.7</b>	Grid 6 <b>47.4</b>
Grid 7 <b>43.5</b>	Grid 8 <b>55.5</b>	Grid 9 <b>55.4</b>	Grid 7 <b>43.8</b>	Grid 8 <b>55.7</b>	Grid 9 <b>55.7</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 55.5V/m



Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz;Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

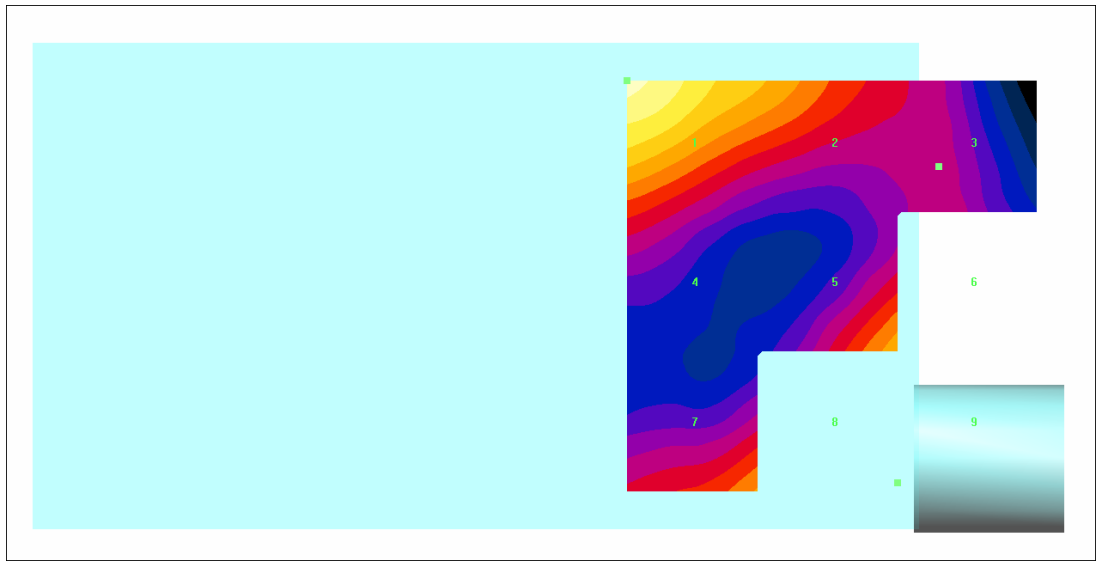
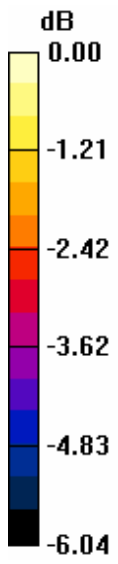
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 52.9 V/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>52.6</b>	Grid 2 <b>45.1</b>	Grid 3 <b>37.7</b>	Grid 1 <b>52.9</b>	Grid 2 <b>45.3</b>	Grid 3 <b>37.9</b>
Grid 4 <b>39.3</b>	Grid 5 <b>44.3</b>	Grid 6 <b>46.0</b>	Grid 4 <b>39.5</b>	Grid 5 <b>44.6</b>	Grid 6 <b>46.2</b>
Grid 7 <b>43.2</b>	Grid 8 <b>54.0</b>	Grid 9 <b>54.0</b>	Grid 7 <b>43.4</b>	Grid 8 <b>54.3</b>	Grid 9 <b>54.3</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 54.0V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

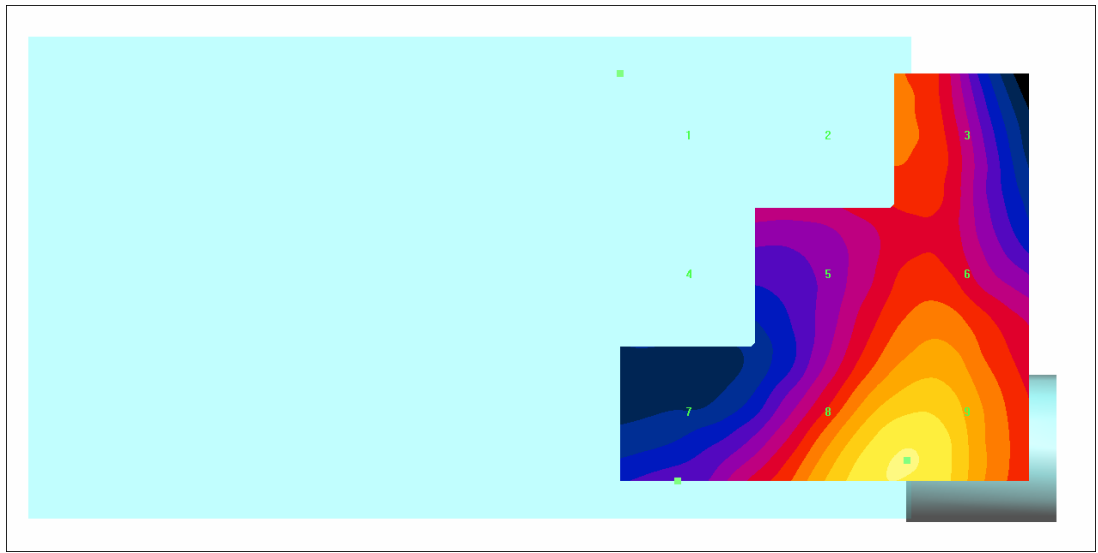
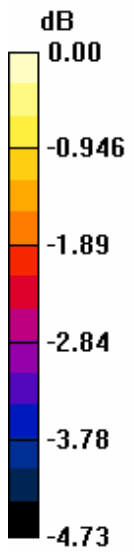
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Low with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 55.8 V/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>59.5</b>	Grid 2 <b>53.5</b>	Grid 3 <b>49.0</b>	Grid 1 <b>59.8</b>	Grid 2 <b>53.7</b>	Grid 3 <b>49.3</b>
Grid 4 <b>49.2</b>	Grid 5 <b>48.0</b>	Grid 6 <b>49.8</b>	Grid 4 <b>49.4</b>	Grid 5 <b>48.3</b>	Grid 6 <b>50.1</b>
Grid 7 <b>44.9</b>	Grid 8 <b>55.4</b>	Grid 9 <b>55.5</b>	Grid 7 <b>45.1</b>	Grid 8 <b>55.7</b>	Grid 9 <b>55.8</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 59.5V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

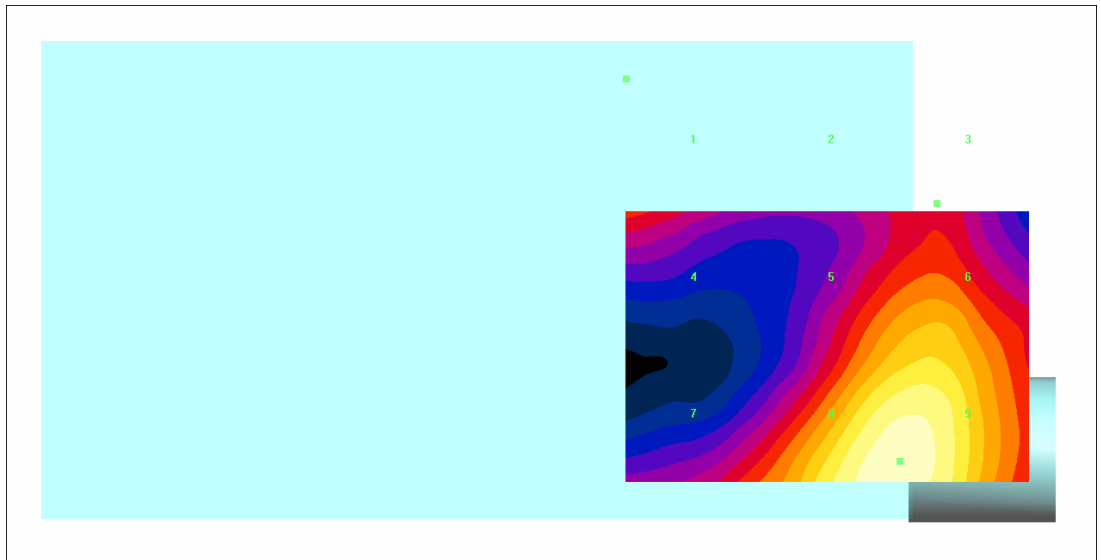
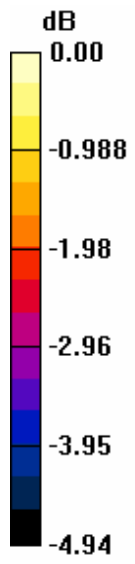
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid with co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 56.1 V/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>56.3</b>	Grid 2 <b>50.2</b>	Grid 3 <b>44.7</b>	Grid 1 <b>56.6</b>	Grid 2 <b>50.5</b>	Grid 3 <b>44.9</b>
Grid 4 <b>44.0</b>	Grid 5 <b>48.0</b>	Grid 6 <b>49.6</b>	Grid 4 <b>44.2</b>	Grid 5 <b>48.3</b>	Grid 6 <b>49.8</b>
Grid 7 <b>44.5</b>	Grid 8 <b>55.7</b>	Grid 9 <b>55.8</b>	Grid 7 <b>44.7</b>	Grid 8 <b>56.0</b>	Grid 9 <b>56.1</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 56.3V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

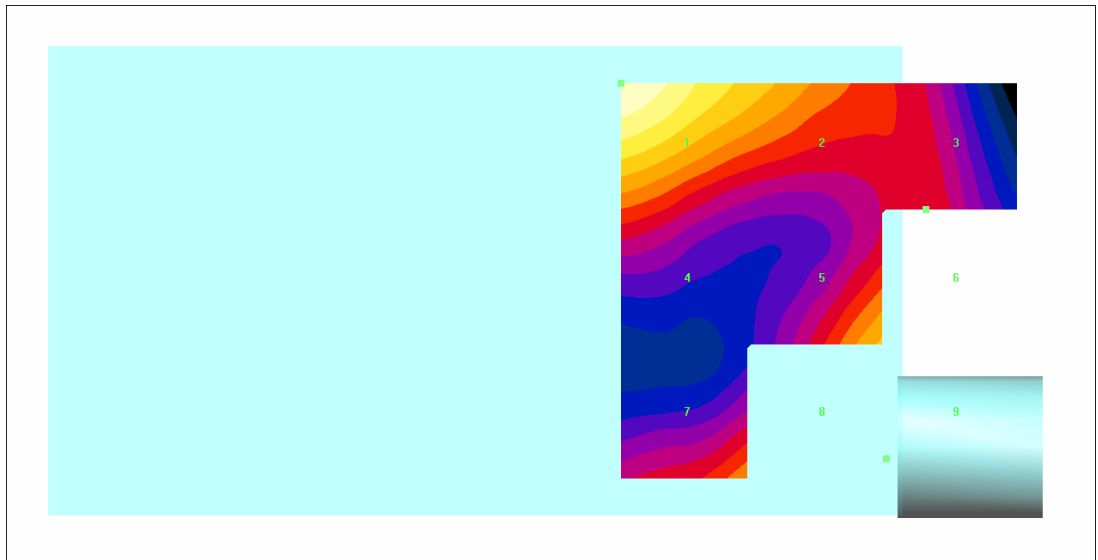
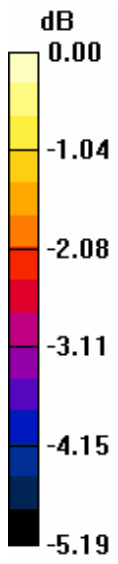
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 54.8 V/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>54.5</b>	Grid 2 <b>47.5</b>	Grid 3 <b>41.7</b>	Grid 1 <b>54.8</b>	Grid 2 <b>47.8</b>	Grid 3 <b>41.9</b>
Grid 4 <b>42.4</b>	Grid 5 <b>46.9</b>	Grid 6 <b>48.1</b>	Grid 4 <b>42.7</b>	Grid 5 <b>47.2</b>	Grid 6 <b>48.4</b>
Grid 7 <b>44.5</b>	Grid 8 <b>54.5</b>	Grid 9 <b>54.5</b>	Grid 7 <b>44.8</b>	Grid 8 <b>54.8</b>	Grid 9 <b>54.8</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 54.5V/m



Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Low/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

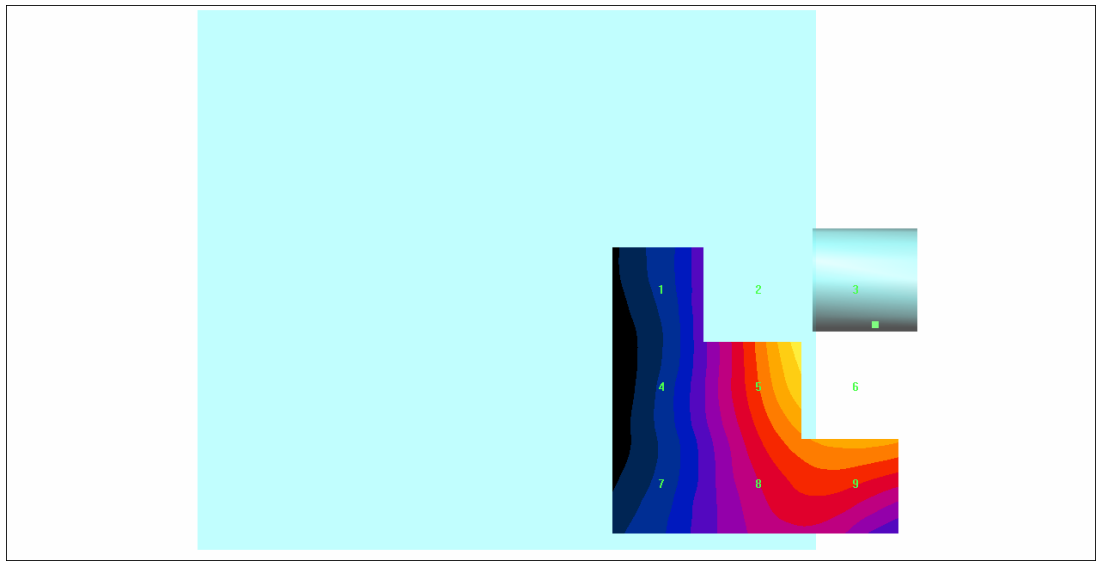
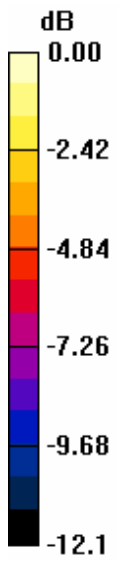
**Maximum value of Total field (slot averaged) = 94.9 V/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
45.8	96.5	117.0	46.1	97.3	117.9
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
46.1	94.2	115.1	46.4	94.9	116.0
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
44.4	71.9	77.7	44.8	72.5	78.3

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 117.0V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

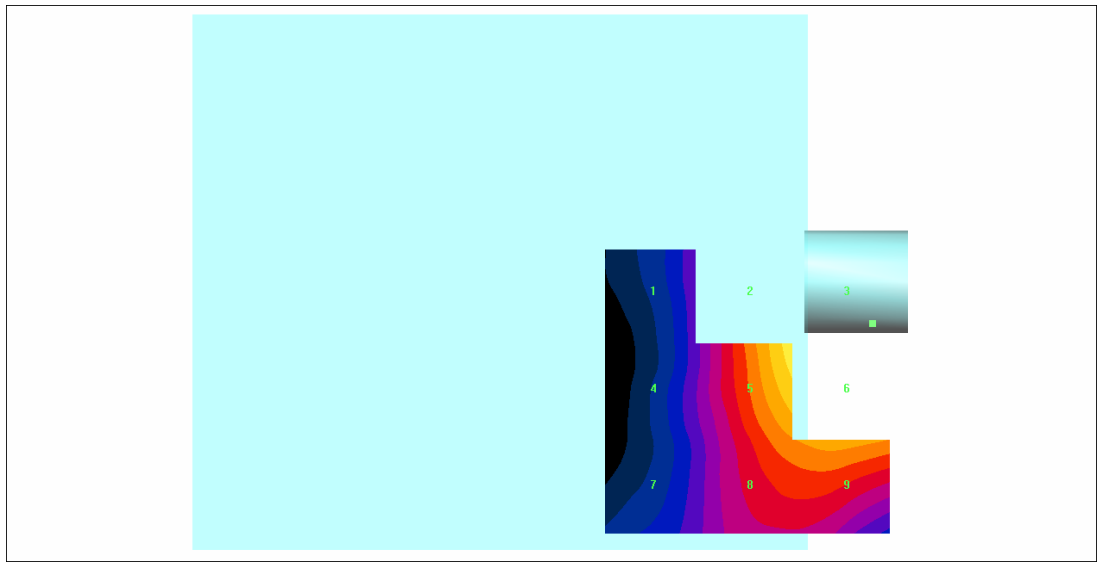
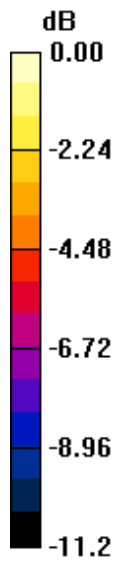
**Maximum value of Total field (slot averaged) = 93.3 V/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>47.3</b>	Grid 2 <b>94.8</b>	Grid 3 <b>112.3</b>	Grid 1 <b>47.7</b>	Grid 2 <b>95.5</b>	Grid 3 <b>113.1</b>
Grid 4 <b>47.4</b>	Grid 5 <b>92.7</b>	Grid 6 <b>110.4</b>	Grid 4 <b>47.7</b>	Grid 5 <b>93.3</b>	Grid 6 <b>111.2</b>
Grid 7 <b>46.3</b>	Grid 8 <b>72.6</b>	Grid 9 <b>77.0</b>	Grid 7 <b>46.7</b>	Grid 8 <b>73.2</b>	Grid 9 <b>77.5</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 112.3V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: E Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

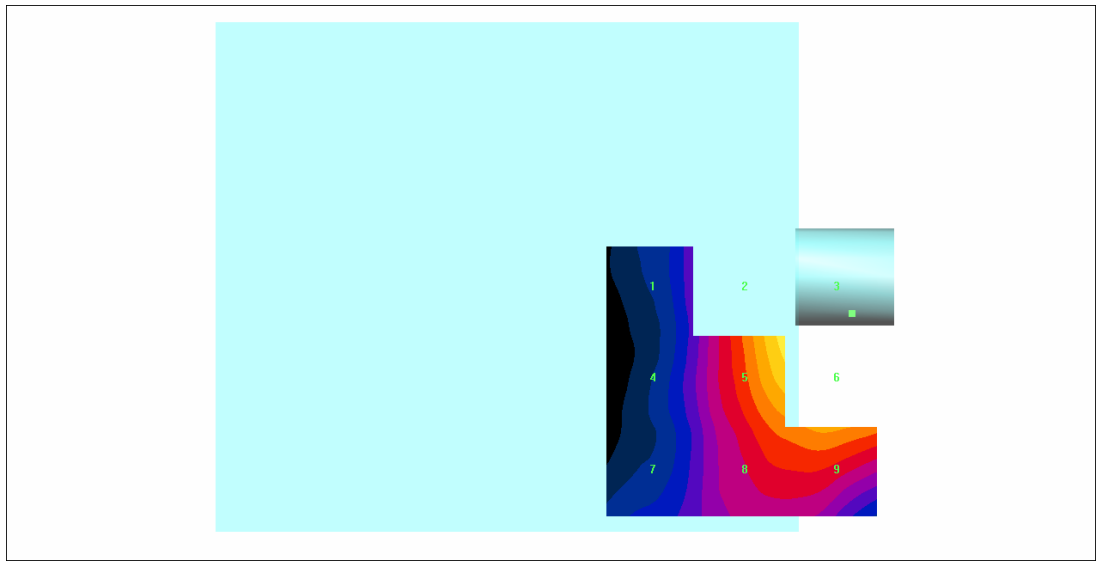
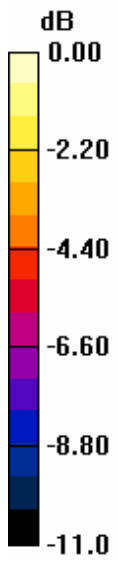
**Maximum value of Total field (slot averaged) = 92.1 V/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>47.0</b>	Grid 2 <b>94.3</b>	Grid 3 <b>111.8</b>	Grid 1 <b>47.4</b>	Grid 2 <b>95.0</b>	Grid 3 <b>112.7</b>
Grid 4 <b>47.2</b>	Grid 5 <b>91.4</b>	Grid 6 <b>109.4</b>	Grid 4 <b>47.6</b>	Grid 5 <b>92.1</b>	Grid 6 <b>110.2</b>
Grid 7 <b>46.7</b>	Grid 8 <b>70.3</b>	Grid 9 <b>75.3</b>	Grid 7 <b>47.0</b>	Grid 8 <b>70.8</b>	Grid 9 <b>75.9</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 111.8V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

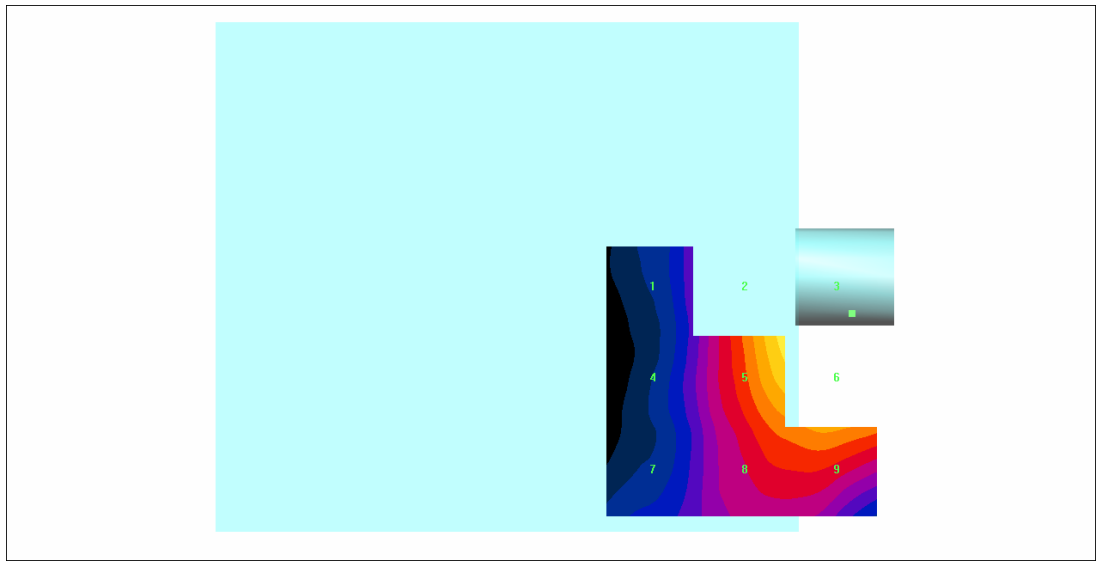
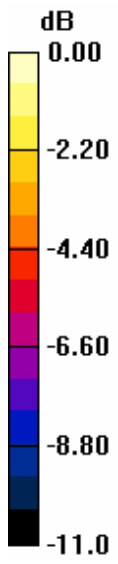
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 92.1 V/m**  
**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>47.0</b>	Grid 2 <b>94.3</b>	Grid 3 <b>111.8</b>	Grid 1 <b>47.4</b>	Grid 2 <b>95.0</b>	Grid 3 <b>112.7</b>
Grid 4 <b>47.2</b>	Grid 5 <b>91.4</b>	Grid 6 <b>109.4</b>	Grid 4 <b>47.6</b>	Grid 5 <b>92.1</b>	Grid 6 <b>110.2</b>
Grid 7 <b>46.7</b>	Grid 8 <b>70.3</b>	Grid 9 <b>75.3</b>	Grid 7 <b>47.0</b>	Grid 8 <b>70.8</b>	Grid 9 <b>75.9</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 111.8V/m



Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

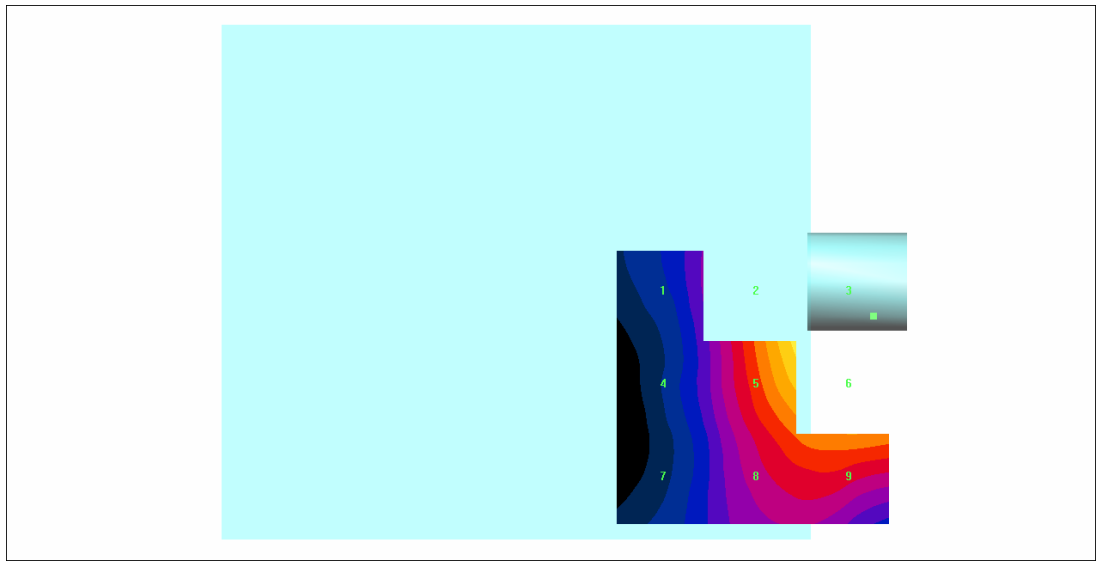
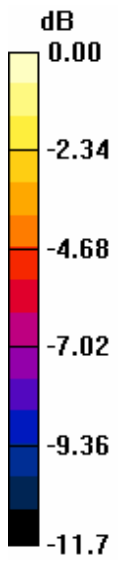
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Low with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 97.0 V/m  
 Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
50.5	99.5	120.9	50.8	100.2	121.8
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
47.5	96.2	117.7	47.9	97.0	118.6
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
44.5	72.0	77.6	44.8	72.5	78.2

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 120.9V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

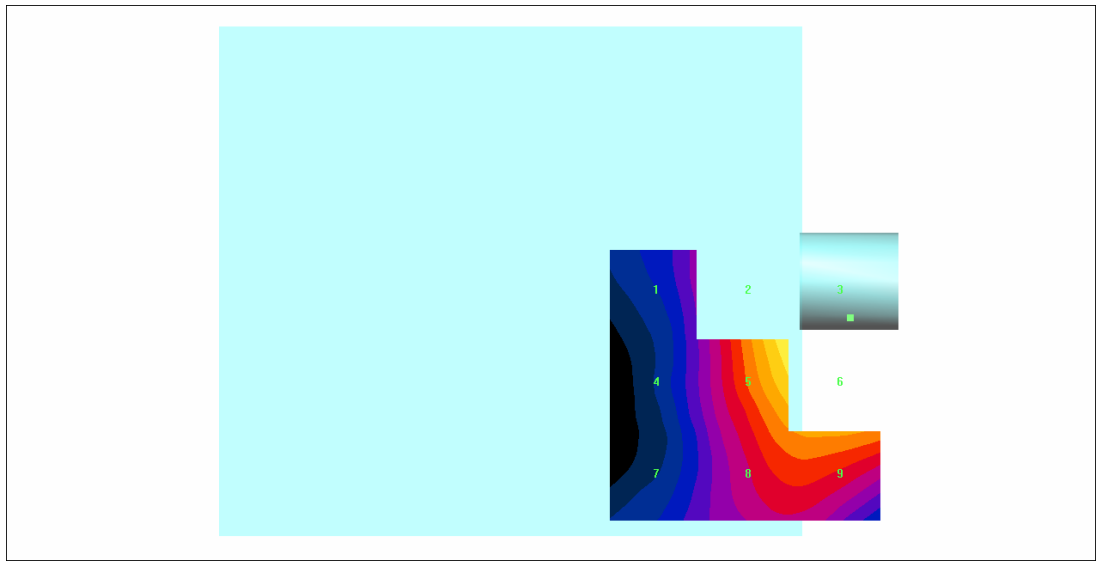
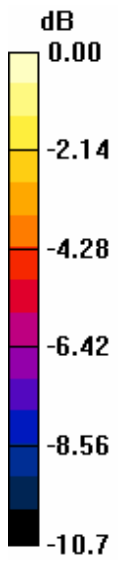
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid with co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 96.4 V/m**  
**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>52.0</b>	Grid 2 <b>98.9</b>	Grid 3 <b>113.1</b>	Grid 1 <b>52.3</b>	Grid 2 <b>99.7</b>	Grid 3 <b>113.9</b>
Grid 4 <b>49.4</b>	Grid 5 <b>95.7</b>	Grid 6 <b>110.9</b>	Grid 4 <b>49.8</b>	Grid 5 <b>96.4</b>	Grid 6 <b>111.7</b>
Grid 7 <b>48.1</b>	Grid 8 <b>74.4</b>	Grid 9 <b>77.3</b>	Grid 7 <b>48.4</b>	Grid 8 <b>74.9</b>	Grid 9 <b>77.9</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 113.1V/m

Date/Time: 2005/7/28 11:15:30 PM Date/Time: 2005/7/28 11:19:45 PM Date/Time: 2005/7/28 11:18:41 PM

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface) Sensor-Surface: 0mm (Fix Surface) Sensor-Surface: 4mm (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 98.4 V/m  
 Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

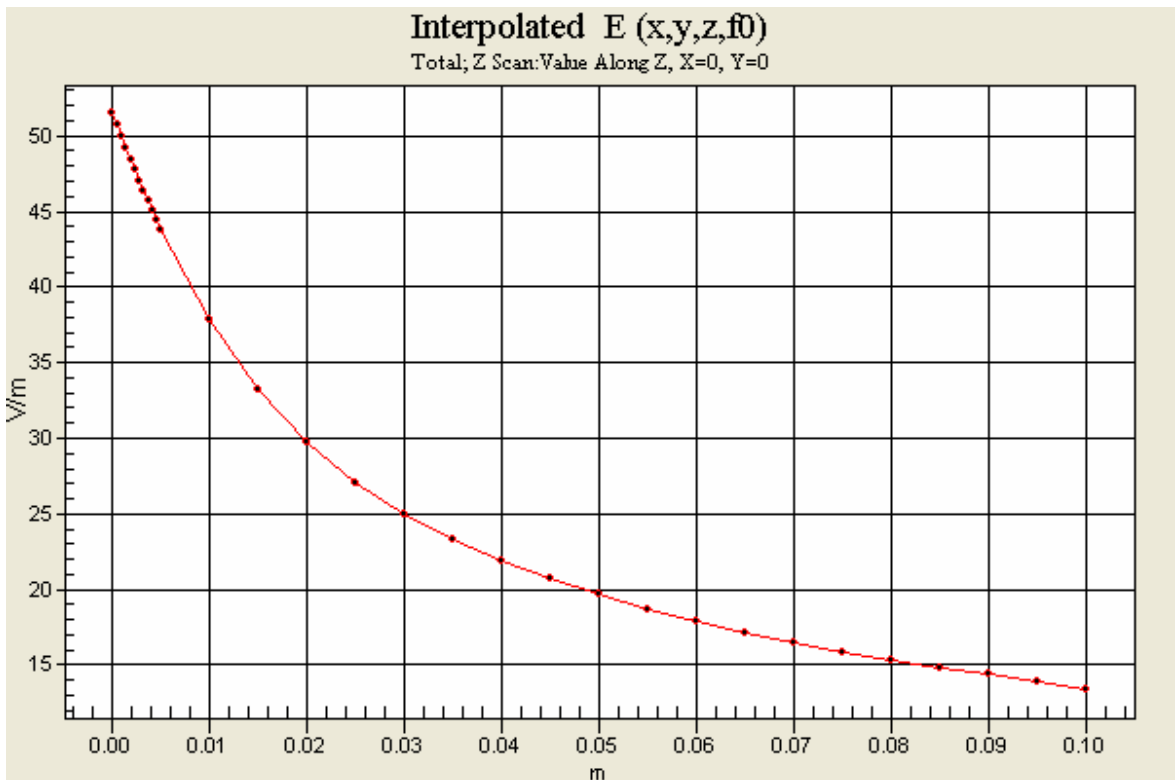
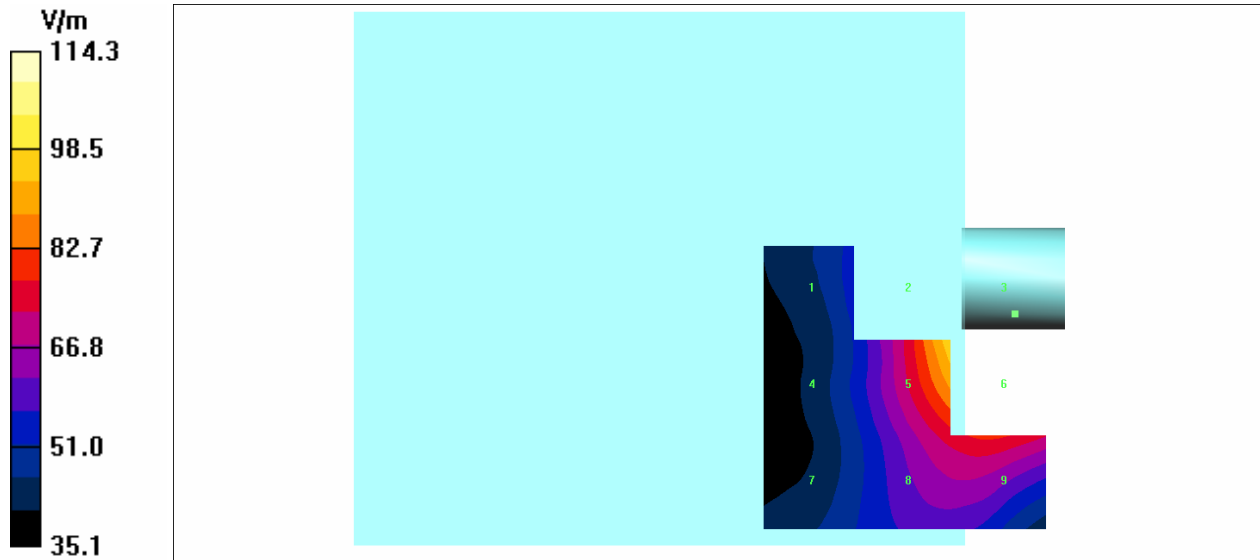
E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>54.6</b>	Grid 2 <b>100.1</b>	Grid 3 <b>114.3</b>	Grid 1 <b>55.0</b>	Grid 2 <b>100.9</b>	Grid 3 <b>115.2</b>
Grid 4 <b>52.4</b>	Grid 5 <b>97.7</b>	Grid 6 <b>112.0</b>	Grid 4 <b>52.8</b>	Grid 5 <b>98.4</b>	Grid 6 <b>112.9</b>
Grid 7 <b>51.0</b>	Grid 8 <b>74.9</b>	Grid 9 <b>78.9</b>	Grid 7 <b>51.3</b>	Grid 8 <b>75.5</b>	Grid 9 <b>79.5</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15

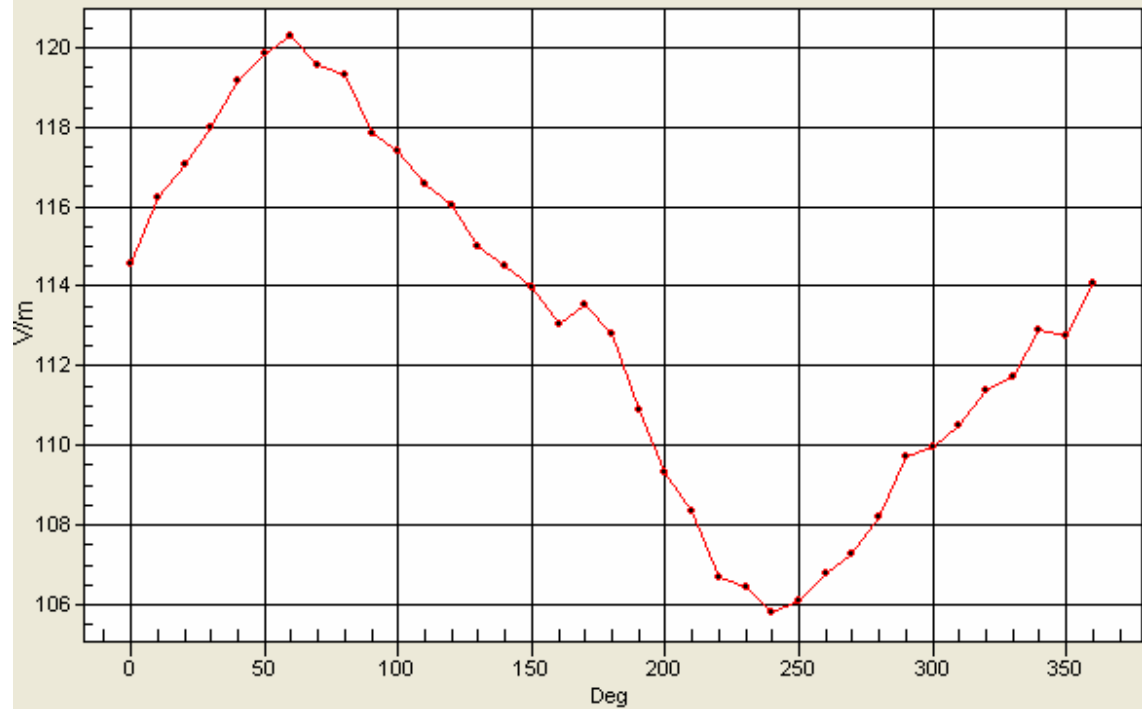
**E Scan - ER probe tip 10mm above Device -High with co-location/Z Scan (1x1x31):**  
**Measurement grid: dx=20mm, dy=20mm, dz=5mm**  
**Maximum value of Total (interpolated) = 51.5 V/m**

**E Scan - ER probe tip 10mm above Device -High with co-location/Rotation (1D): 37 rotation steps; E-Field Max Isotropy Error = ±0.57 dB;**



# E(roll)

E\_tot; ; E-Field Max Isotropy Error = ? .57 dB;



Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA835(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: E Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High with co-location and Backlight on/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

**Maximum value of Total field (slot averaged) = 94.1 V/m**

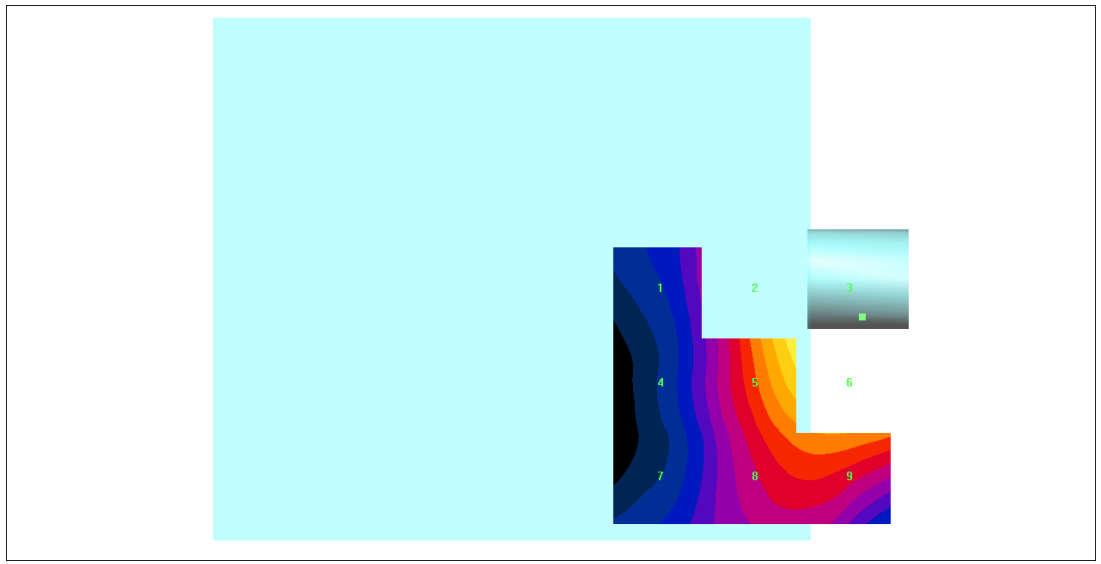
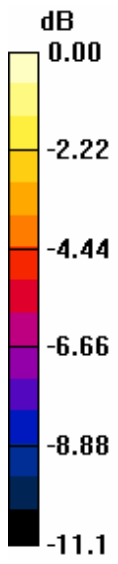
**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>49.9</b>	Grid 2 <b>96.4</b>	Grid 3 <b>112.8</b>	Grid 1 <b>50.2</b>	Grid 2 <b>97.1</b>	Grid 3 <b>113.6</b>
Grid 4 <b>47.3</b>	Grid 5 <b>93.4</b>	Grid 6 <b>109.7</b>	Grid 4 <b>47.7</b>	Grid 5 <b>94.1</b>	Grid 6 <b>110.6</b>
Grid 7 <b>46.2</b>	Grid 8 <b>71.1</b>	Grid 9 <b>74.4</b>	Grid 7 <b>46.5</b>	Grid 8 <b>71.6</b>	Grid 9 <b>74.9</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 112.8V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Low/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

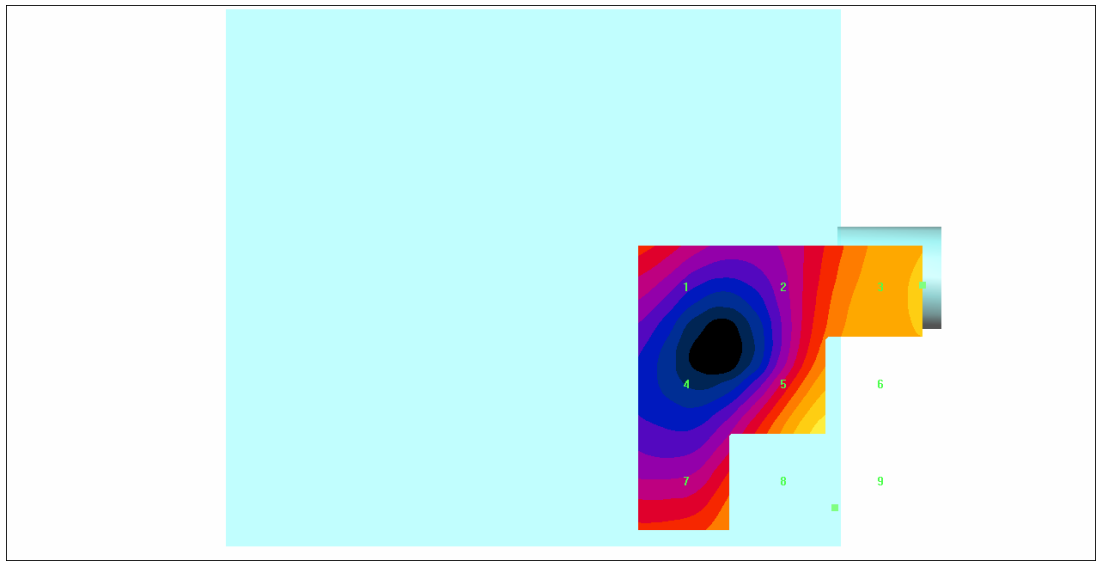
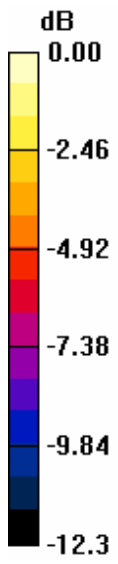
**Maximum value of Total field (slot averaged) = 34.5 V/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>23.2</b>	Grid 2 <b>24.6</b>	Grid 3 <b>29.7</b>	Grid 1 <b>23.3</b>	Grid 2 <b>24.7</b>	Grid 3 <b>29.8</b>
Grid 4 <b>18.2</b>	Grid 5 <b>34.3</b>	Grid 6 <b>35.5</b>	Grid 4 <b>18.3</b>	Grid 5 <b>34.5</b>	Grid 6 <b>35.6</b>
Grid 7 <b>26.5</b>	Grid 8 <b>42.5</b>	Grid 9 <b>42.6</b>	Grid 7 <b>26.7</b>	Grid 8 <b>42.7</b>	Grid 9 <b>42.8</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 42.6V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid/Hearing Aid Compatibility Test**

**(101x101x1): Measurement grid: dx=5mm, dy=5mm**

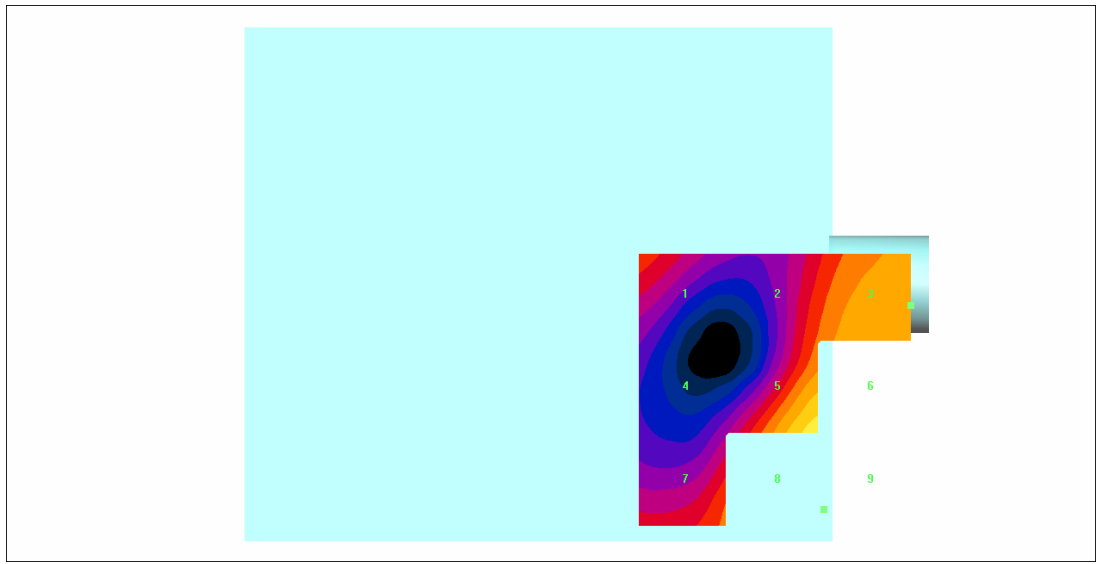
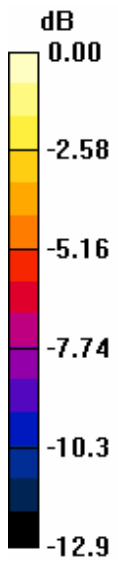
**Maximum value of Total field (slot averaged) = 35.9 V/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>24.0</b>	Grid 2 <b>25.1</b>	Grid 3 <b>28.8</b>	Grid 1 <b>24.1</b>	Grid 2 <b>25.3</b>	Grid 3 <b>29.0</b>
Grid 4 <b>18.1</b>	Grid 5 <b>35.7</b>	Grid 6 <b>36.7</b>	Grid 4 <b>18.2</b>	Grid 5 <b>35.9</b>	Grid 6 <b>36.9</b>
Grid 7 <b>25.7</b>	Grid 8 <b>44.6</b>	Grid 9 <b>44.7</b>	Grid 7 <b>25.8</b>	Grid 8 <b>44.8</b>	Grid 9 <b>44.9</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 44.7V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz;Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

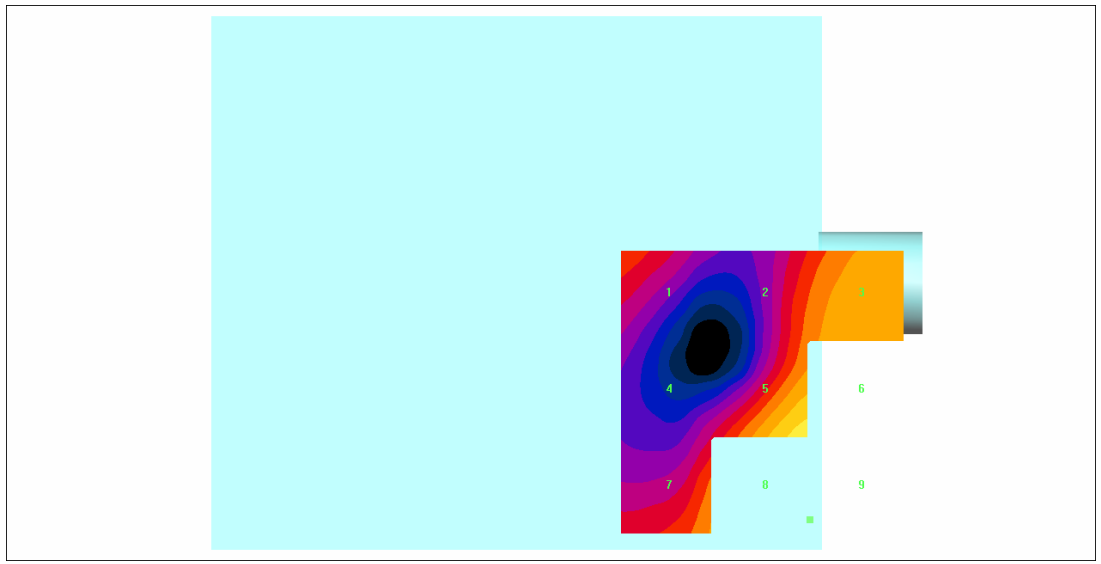
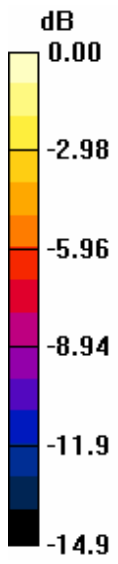
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 36.8 V/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>23.9</b>	Grid 2 <b>25.1</b>	Grid 3 <b>29.1</b>	Grid 1 <b>24.0</b>	Grid 2 <b>25.2</b>	Grid 3 <b>29.3</b>
Grid 4 <b>19.1</b>	Grid 5 <b>36.6</b>	Grid 6 <b>37.5</b>	Grid 4 <b>19.2</b>	Grid 5 <b>36.8</b>	Grid 6 <b>37.7</b>
Grid 7 <b>27.2</b>	Grid 8 <b>47.3</b>	Grid 9 <b>47.4</b>	Grid 7 <b>27.3</b>	Grid 8 <b>47.6</b>	Grid 9 <b>47.6</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 47.4V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

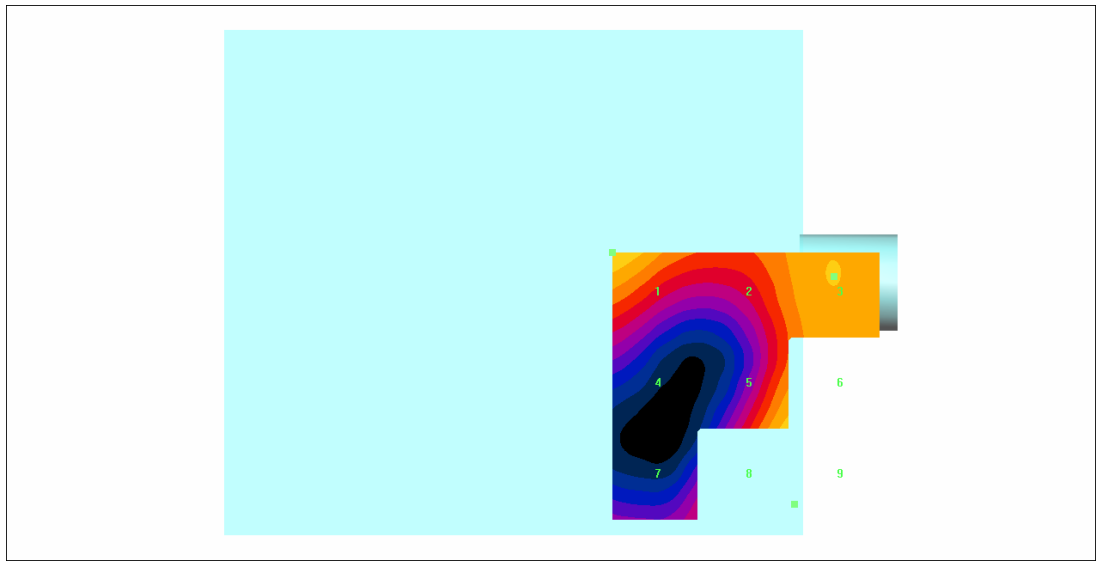
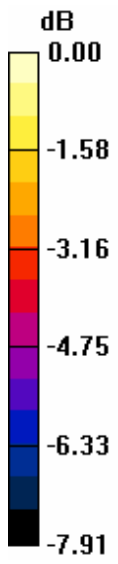
**E Scan - ER probe tip 10mm above Device -Low with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 36.7 V/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>36.5</b>	Grid 2 <b>32.5</b>	Grid 3 <b>34.3</b>	Grid 1 <b>36.7</b>	Grid 2 <b>32.7</b>	Grid 3 <b>34.5</b>
Grid 4 <b>26.0</b>	Grid 5 <b>35.5</b>	Grid 6 <b>36.6</b>	Grid 4 <b>26.1</b>	Grid 5 <b>35.7</b>	Grid 6 <b>36.8</b>
Grid 7 <b>26.9</b>	Grid 8 <b>43.4</b>	Grid 9 <b>43.6</b>	Grid 7 <b>27.0</b>	Grid 8 <b>43.7</b>	Grid 9 <b>43.8</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 43.6V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

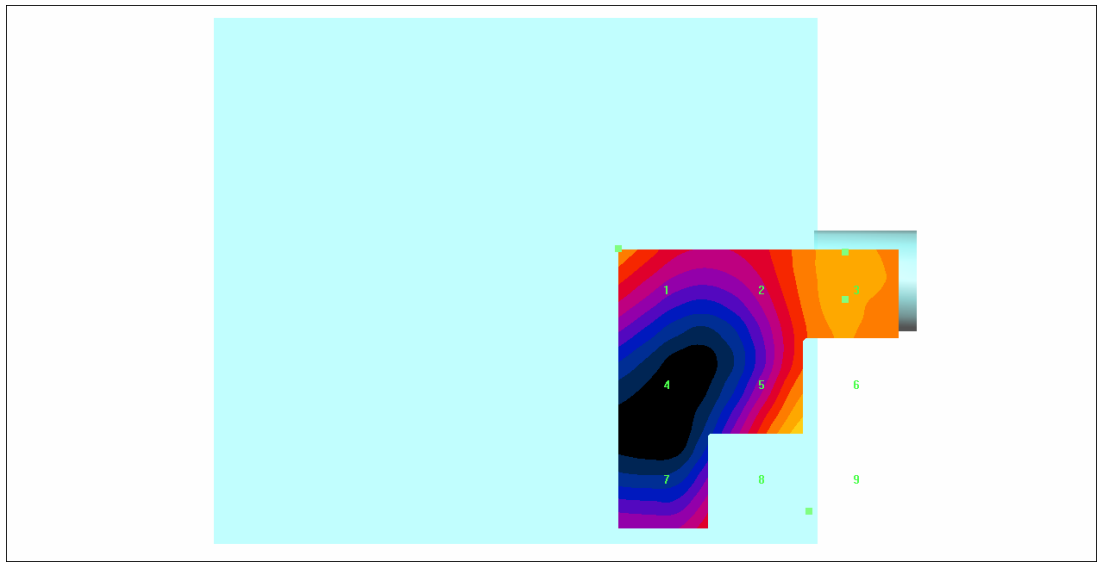
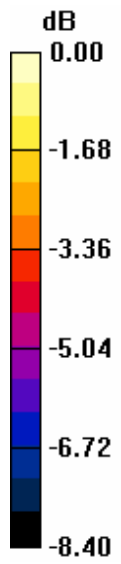
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -Mid with co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 36.7 V/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>32.2</b>	Grid 2 <b>31.6</b>	Grid 3 <b>33.5</b>	Grid 1 <b>32.4</b>	Grid 2 <b>31.8</b>	Grid 3 <b>33.7</b>
Grid 4 <b>22.7</b>	Grid 5 <b>36.5</b>	Grid 6 <b>37.6</b>	Grid 4 <b>22.9</b>	Grid 5 <b>36.7</b>	Grid 6 <b>37.8</b>
Grid 7 <b>28.1</b>	Grid 8 <b>44.8</b>	Grid 9 <b>44.9</b>	Grid 7 <b>28.3</b>	Grid 8 <b>45.0</b>	Grid 9 <b>45.1</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 44.9V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_E\_SCAN\_CDMA1900(Open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1.01  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>  
 Phantom section: E Device Section  
 Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

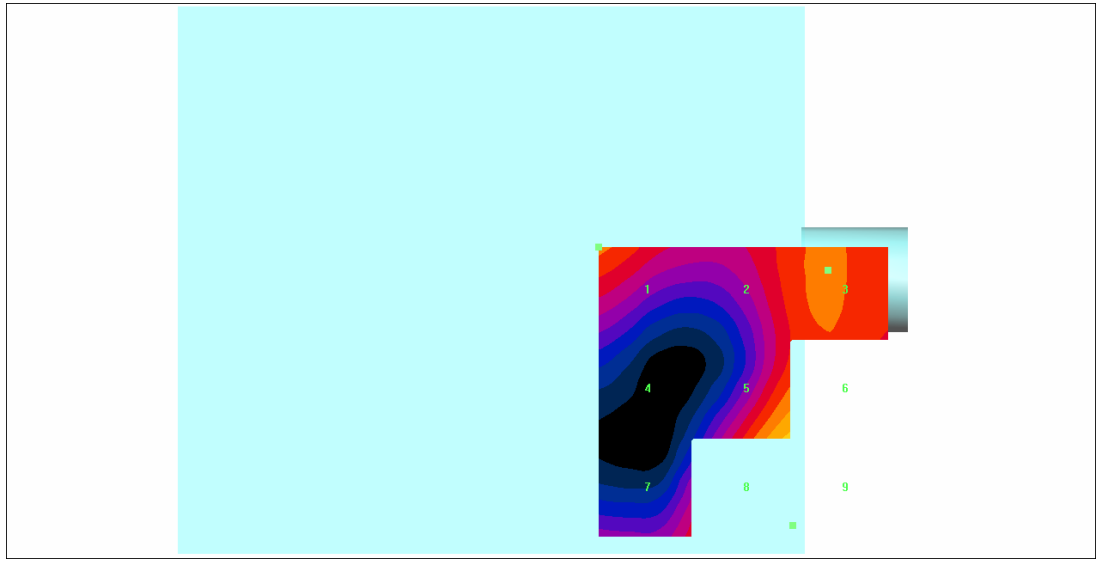
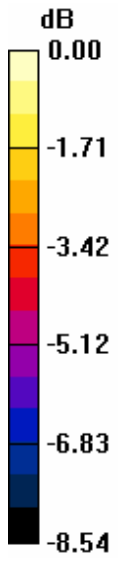
- Probe: ER3DV6 - SN2345; ConvF(1, 1, 1); Calibrated: 2005/6/3
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**E Scan - ER probe tip 10mm above Device -High with co-location/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 36.6 V/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

E in V/m (Time averaged)    E in V/m (Slot averaged)

Grid 1 <b>32.1</b>	Grid 2 <b>30.4</b>	Grid 3 <b>31.9</b>	Grid 1 <b>32.2</b>	Grid 2 <b>30.5</b>	Grid 3 <b>32.1</b>
Grid 4 <b>23.3</b>	Grid 5 <b>36.4</b>	Grid 6 <b>37.2</b>	Grid 4 <b>23.4</b>	Grid 5 <b>36.6</b>	Grid 6 <b>37.4</b>
Grid 7 <b>28.3</b>	Grid 8 <b>46.2</b>	Grid 9 <b>46.3</b>	Grid 7 <b>28.4</b>	Grid 8 <b>46.5</b>	Grid 9 <b>46.5</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 46.3V/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Low/Hearing Aid**

**Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

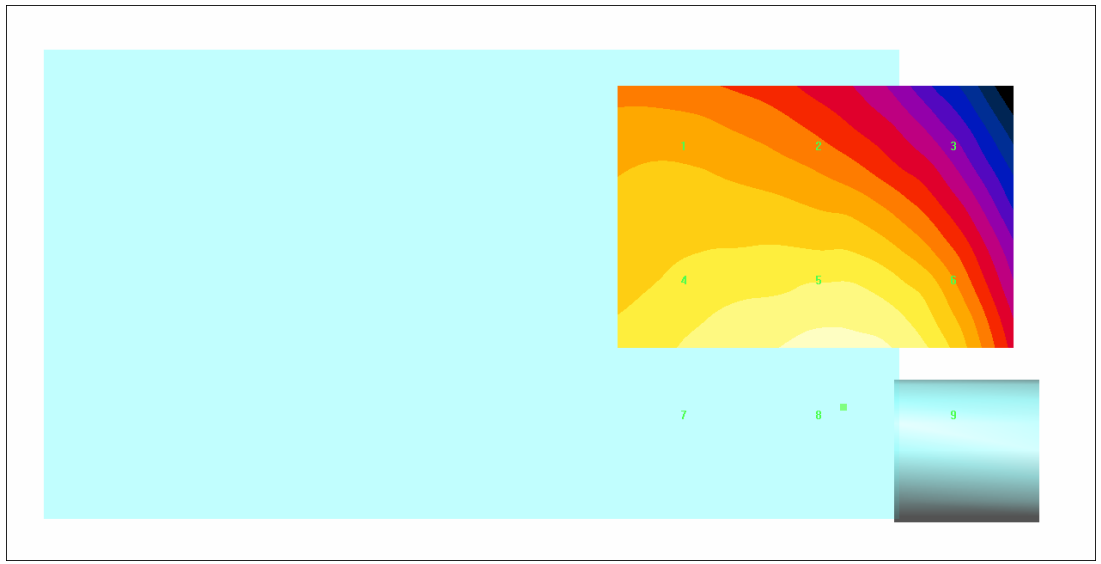
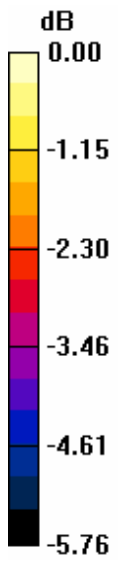
**Maximum value of Total field (slot averaged) = 0.165 A/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.145</b>	Grid 2 <b>0.144</b>	Grid 3 <b>0.136</b>	Grid 1 <b>0.146</b>	Grid 2 <b>0.145</b>	Grid 3 <b>0.137</b>
Grid 4 <b>0.159</b>	Grid 5 <b>0.164</b>	Grid 6 <b>0.162</b>	Grid 4 <b>0.160</b>	Grid 5 <b>0.165</b>	Grid 6 <b>0.163</b>
Grid 7 <b>0.162</b>	Grid 8 <b>0.168</b>	Grid 9 <b>0.167</b>	Grid 7 <b>0.163</b>	Grid 8 <b>0.169</b>	Grid 9 <b>0.168</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.168A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

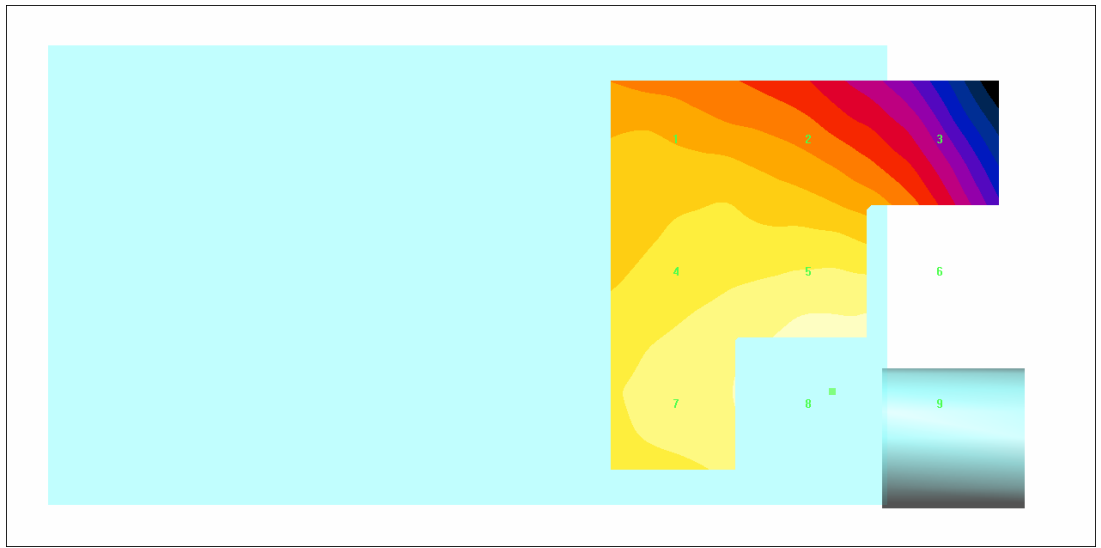
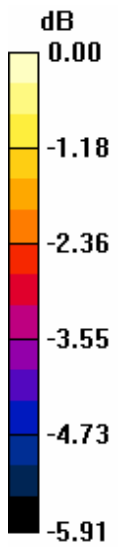
**H Scan - H3DV6 probe center 10mm above Device Reference-Mid/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.166 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.147</b>	Grid 2 <b>0.146</b>	Grid 3 <b>0.137</b>	Grid 1 <b>0.148</b>	Grid 2 <b>0.147</b>	Grid 3 <b>0.139</b>
Grid 4 <b>0.158</b>	Grid 5 <b>0.165</b>	Grid 6 <b>0.165</b>	Grid 4 <b>0.159</b>	Grid 5 <b>0.166</b>	Grid 6 <b>0.166</b>
Grid 7 <b>0.161</b>	Grid 8 <b>0.168</b>	Grid 9 <b>0.168</b>	Grid 7 <b>0.162</b>	Grid 8 <b>0.169</b>	Grid 9 <b>0.169</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 0.168A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

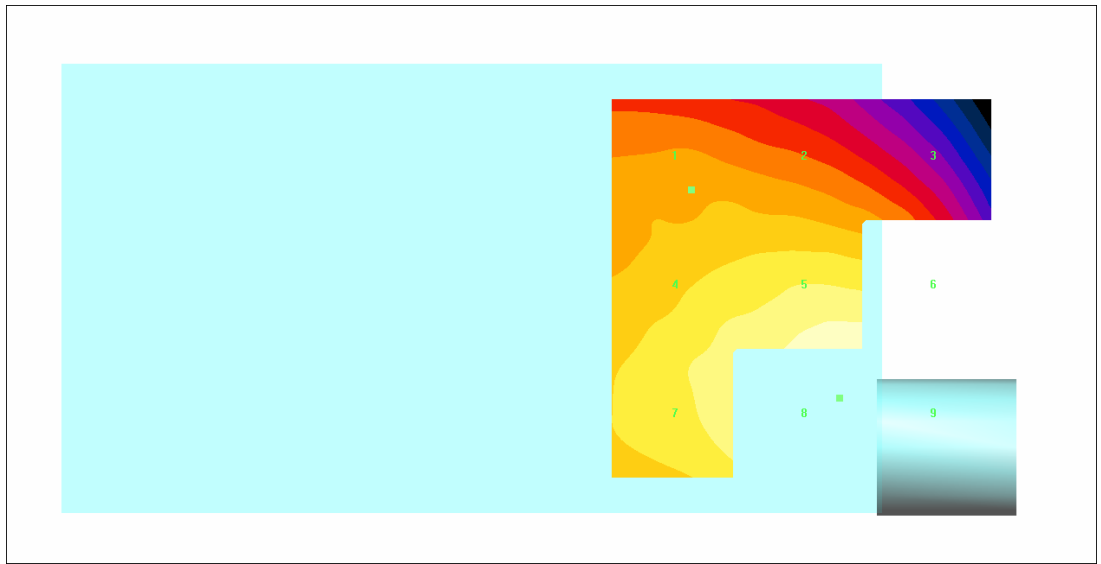
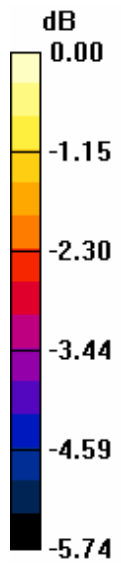
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-High/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.163 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.141</b>	Grid 2 <b>0.141</b>	Grid 3 <b>0.135</b>	Grid 1 <b>0.142</b>	Grid 2 <b>0.142</b>	Grid 3 <b>0.136</b>
Grid 4 <b>0.153</b>	Grid 5 <b>0.162</b>	Grid 6 <b>0.162</b>	Grid 4 <b>0.154</b>	Grid 5 <b>0.163</b>	Grid 6 <b>0.163</b>
Grid 7 <b>0.155</b>	Grid 8 <b>0.165</b>	Grid 9 <b>0.165</b>	Grid 7 <b>0.156</b>	Grid 8 <b>0.167</b>	Grid 9 <b>0.166</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.165A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

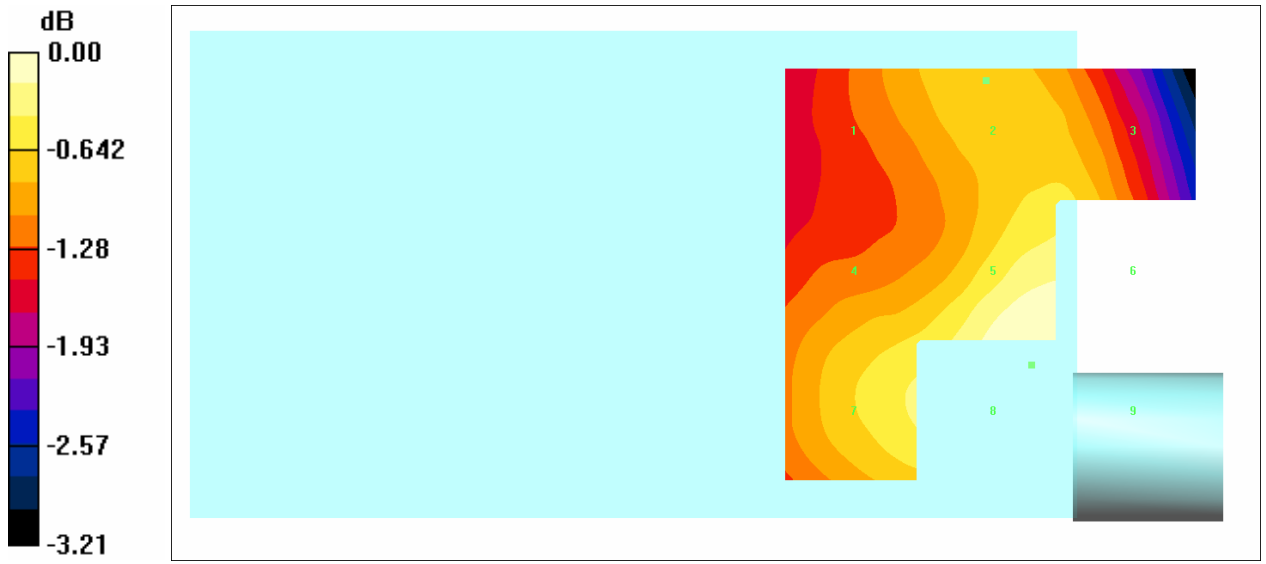
**H Scan - H3DV6 probe center 10mm above Device Reference-Low with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.216 A/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.195</b>	Grid 2 <b>0.201</b>	Grid 3 <b>0.201</b>	Grid 1 <b>0.196</b>	Grid 2 <b>0.203</b>	Grid 3 <b>0.203</b>
Grid 4 <b>0.201</b>	Grid 5 <b>0.215</b>	Grid 6 <b>0.214</b>	Grid 4 <b>0.202</b>	Grid 5 <b>0.216</b>	Grid 6 <b>0.216</b>
Grid 7 <b>0.206</b>	Grid 8 <b>0.215</b>	Grid 9 <b>0.215</b>	Grid 7 <b>0.207</b>	Grid 8 <b>0.217</b>	Grid 9 <b>0.216</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Mid with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

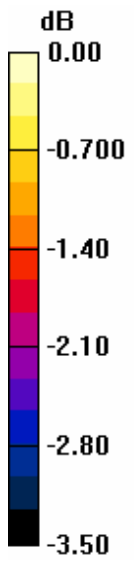
**Maximum value of Total field (slot averaged) = 0.218 A/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.194</b>	Grid 2 <b>0.201</b>	Grid 3 <b>0.199</b>	Grid 1 <b>0.196</b>	Grid 2 <b>0.202</b>	Grid 3 <b>0.201</b>
Grid 4 <b>0.209</b>	Grid 5 <b>0.217</b>	Grid 6 <b>0.215</b>	Grid 4 <b>0.211</b>	Grid 5 <b>0.218</b>	Grid 6 <b>0.217</b>
Grid 7 <b>0.213</b>	Grid 8 <b>0.218</b>	Grid 9 <b>0.216</b>	Grid 7 <b>0.215</b>	Grid 8 <b>0.219</b>	Grid 9 <b>0.217</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.218A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(Close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-High with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.214 A/m**

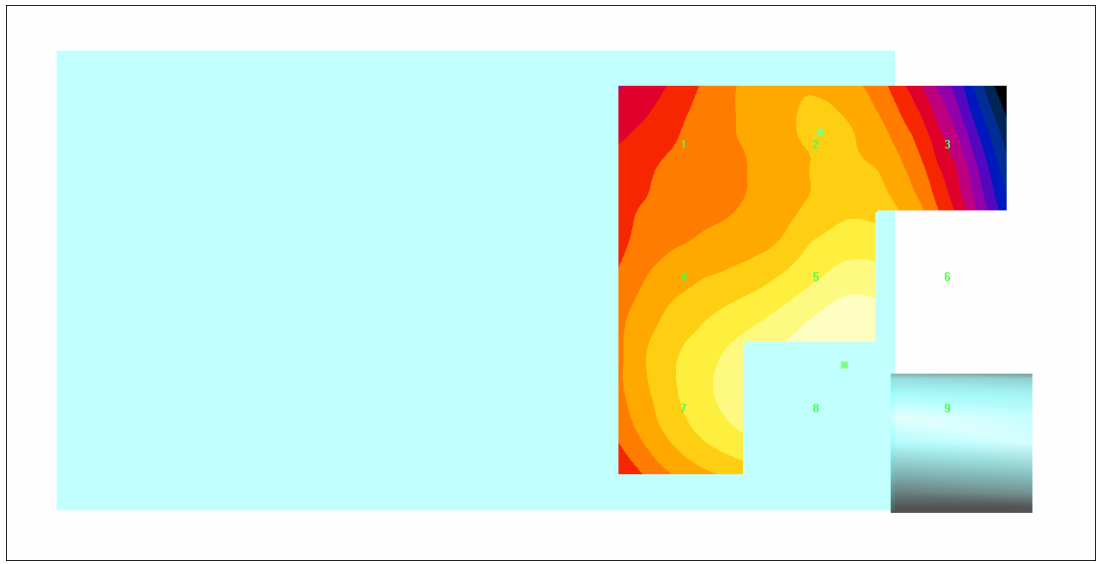
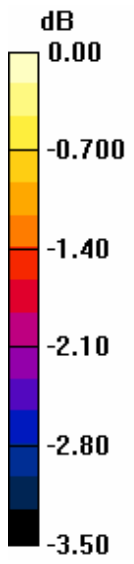
**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.187</b>	Grid 2 <b>0.196</b>	Grid 3 <b>0.195</b>	Grid 1 <b>0.189</b>	Grid 2 <b>0.197</b>	Grid 3 <b>0.196</b>
Grid 4 <b>0.203</b>	Grid 5 <b>0.213</b>	Grid 6 <b>0.211</b>	Grid 4 <b>0.205</b>	Grid 5 <b>0.214</b>	Grid 6 <b>0.213</b>
Grid 7 <b>0.205</b>	Grid 8 <b>0.213</b>	Grid 9 <b>0.212</b>	Grid 7 <b>0.207</b>	Grid 8 <b>0.215</b>	Grid 9 <b>0.214</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 0.213A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.018

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Low/Hearing Aid**

**Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

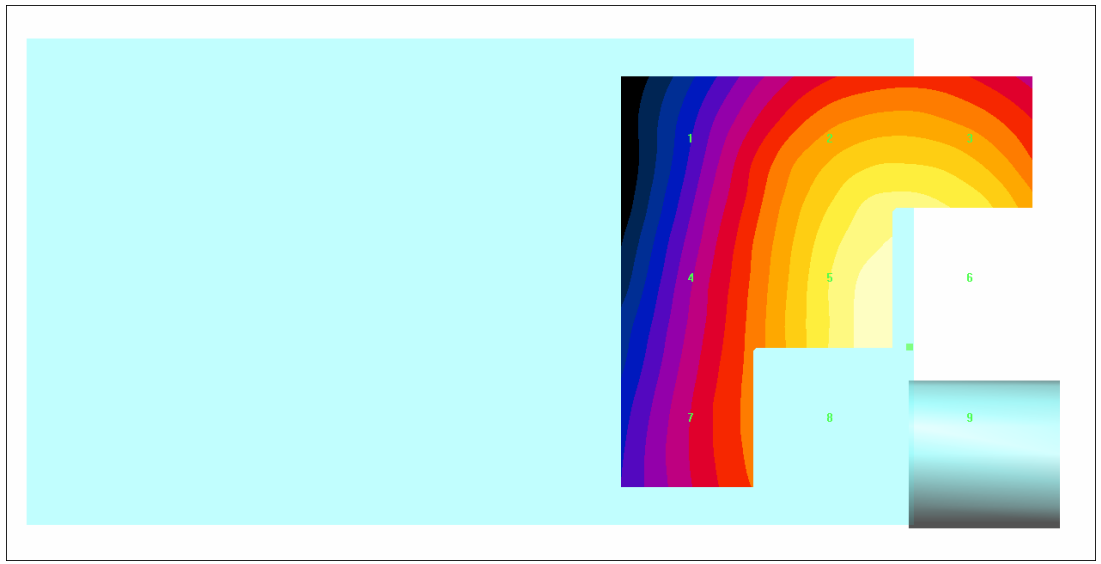
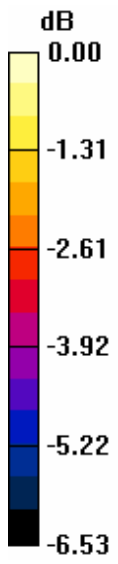
**Maximum value of Total field (slot averaged) = 0.176 A/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.127</b>	Grid 2 <b>0.162</b>	Grid 3 <b>0.162</b>	Grid 1 <b>0.128</b>	Grid 2 <b>0.163</b>	Grid 3 <b>0.164</b>
Grid 4 <b>0.132</b>	Grid 5 <b>0.174</b>	Grid 6 <b>0.175</b>	Grid 4 <b>0.134</b>	Grid 5 <b>0.176</b>	Grid 6 <b>0.177</b>
Grid 7 <b>0.133</b>	Grid 8 <b>0.174</b>	Grid 9 <b>0.175</b>	Grid 7 <b>0.134</b>	Grid 8 <b>0.176</b>	Grid 9 <b>0.177</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.175A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

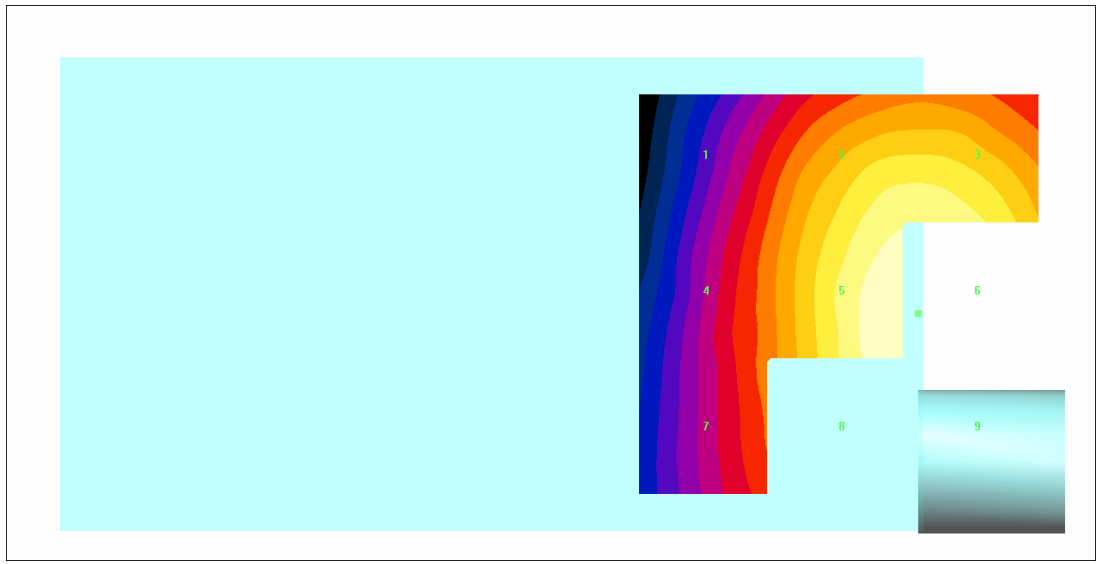
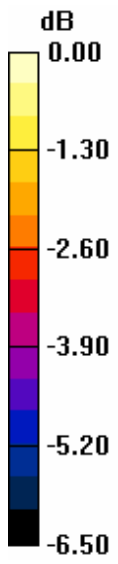
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Mid/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.156 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)      H in A/m (Slot averaged)

Grid 1 <b>0.115</b>	Grid 2 <b>0.147</b>	Grid 3 <b>0.147</b>	Grid 1 <b>0.116</b>	Grid 2 <b>0.148</b>	Grid 3 <b>0.148</b>
Grid 4 <b>0.118</b>	Grid 5 <b>0.155</b>	Grid 6 <b>0.155</b>	Grid 4 <b>0.119</b>	Grid 5 <b>0.156</b>	Grid 6 <b>0.156</b>
Grid 7 <b>0.118</b>	Grid 8 <b>0.153</b>	Grid 9 <b>0.153</b>	Grid 7 <b>0.119</b>	Grid 8 <b>0.155</b>	Grid 9 <b>0.155</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.155A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

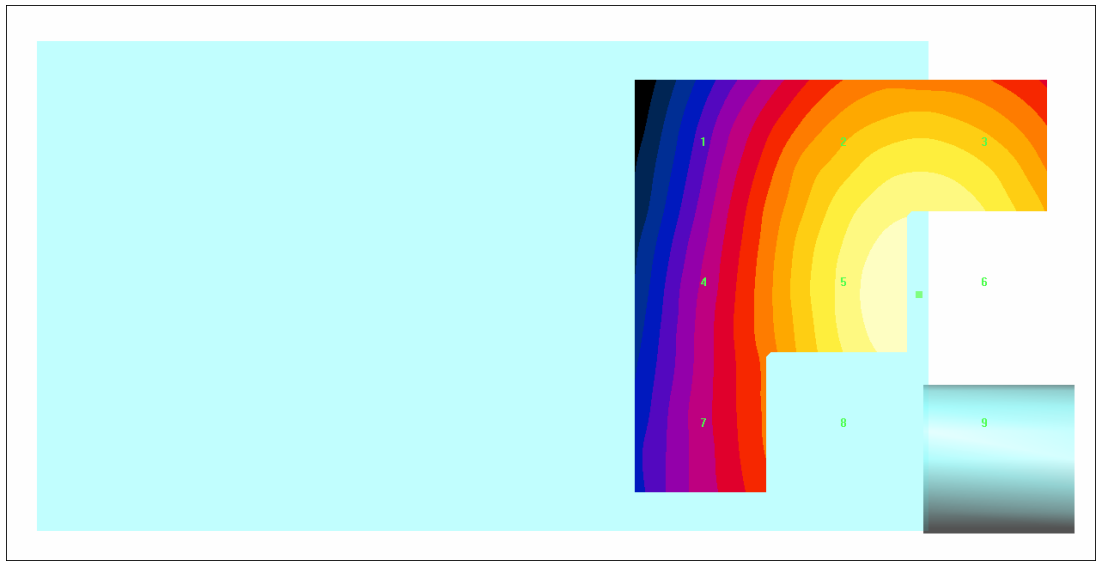
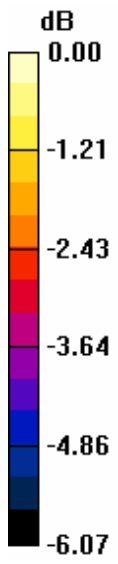
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-High/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.155 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.118</b>	Grid 2 <b>0.146</b>	Grid 3 <b>0.147</b>	Grid 1 <b>0.119</b>	Grid 2 <b>0.148</b>	Grid 3 <b>0.148</b>
Grid 4 <b>0.120</b>	Grid 5 <b>0.154</b>	Grid 6 <b>0.154</b>	Grid 4 <b>0.121</b>	Grid 5 <b>0.155</b>	Grid 6 <b>0.156</b>
Grid 7 <b>0.119</b>	Grid 8 <b>0.150</b>	Grid 9 <b>0.150</b>	Grid 7 <b>0.120</b>	Grid 8 <b>0.151</b>	Grid 9 <b>0.152</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.154A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

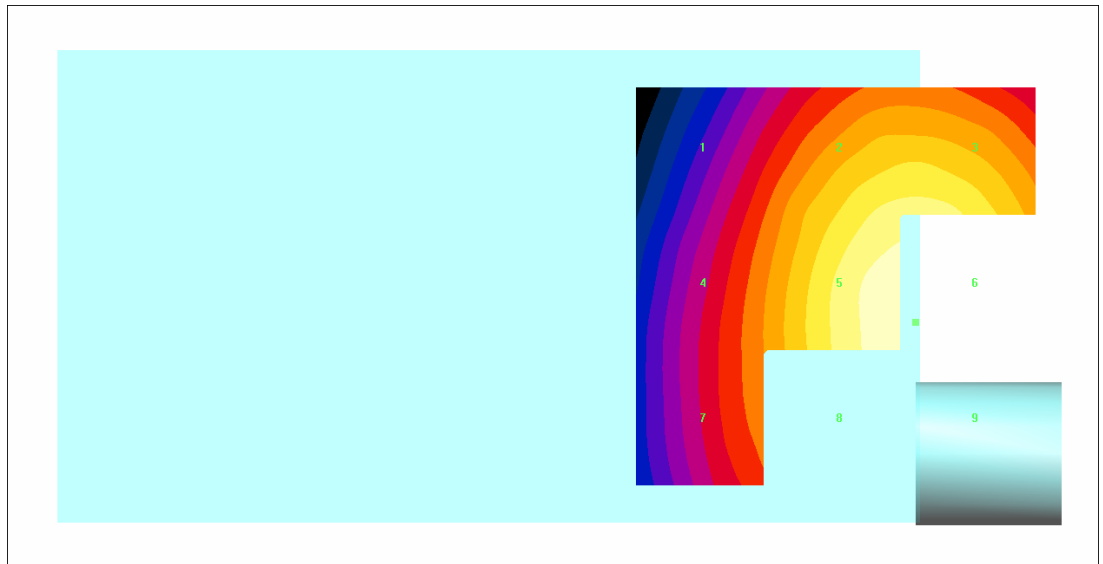
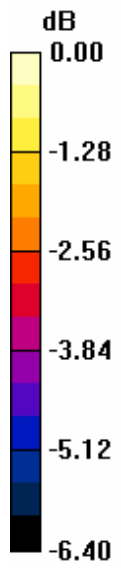
**H Scan - H3DV6 probe center 10mm above Device Reference-Low with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.179 A/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)      H in A/m (Slot averaged)

Grid 1 <b>0.133</b>	Grid 2 <b>0.166</b>	Grid 3 <b>0.166</b>	Grid 1 <b>0.134</b>	Grid 2 <b>0.167</b>	Grid 3 <b>0.167</b>
Grid 4 <b>0.140</b>	Grid 5 <b>0.178</b>	Grid 6 <b>0.179</b>	Grid 4 <b>0.142</b>	Grid 5 <b>0.179</b>	Grid 6 <b>0.180</b>
Grid 7 <b>0.140</b>	Grid 8 <b>0.176</b>	Grid 9 <b>0.177</b>	Grid 7 <b>0.141</b>	Grid 8 <b>0.178</b>	Grid 9 <b>0.178</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 0.179A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

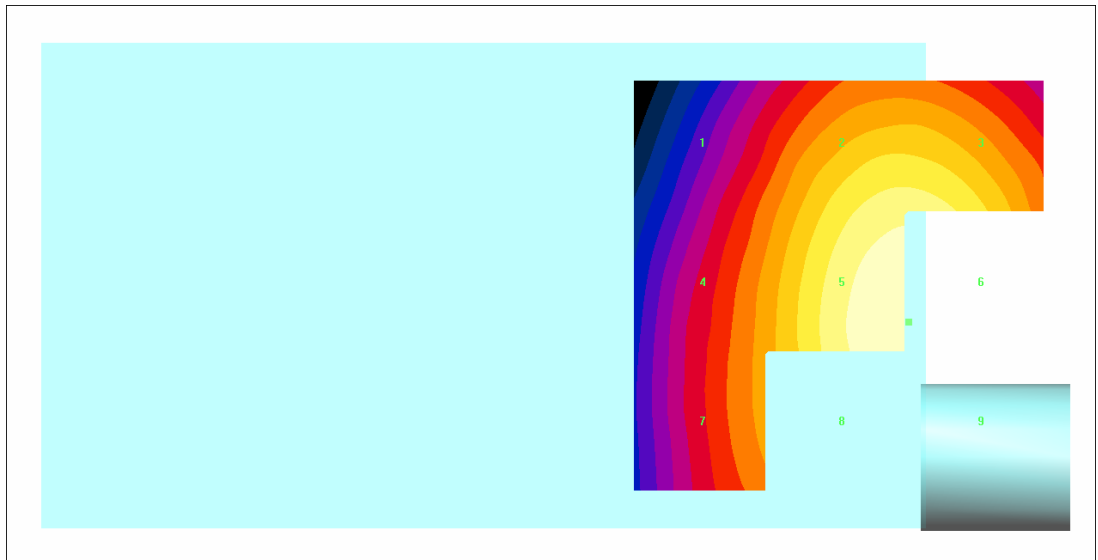
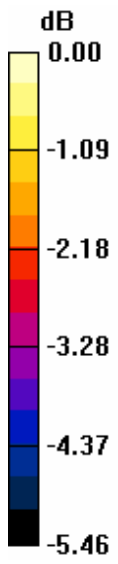
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Mid with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.168 A/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.132</b>	Grid 2 <b>0.158</b>	Grid 3 <b>0.158</b>	Grid 1 <b>0.134</b>	Grid 2 <b>0.159</b>	Grid 3 <b>0.159</b>
Grid 4 <b>0.139</b>	Grid 5 <b>0.167</b>	Grid 6 <b>0.167</b>	Grid 4 <b>0.140</b>	Grid 5 <b>0.168</b>	Grid 6 <b>0.168</b>
Grid 7 <b>0.139</b>	Grid 8 <b>0.166</b>	Grid 9 <b>0.166</b>	Grid 7 <b>0.140</b>	Grid 8 <b>0.167</b>	Grid 9 <b>0.167</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.167A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(close)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1.018

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

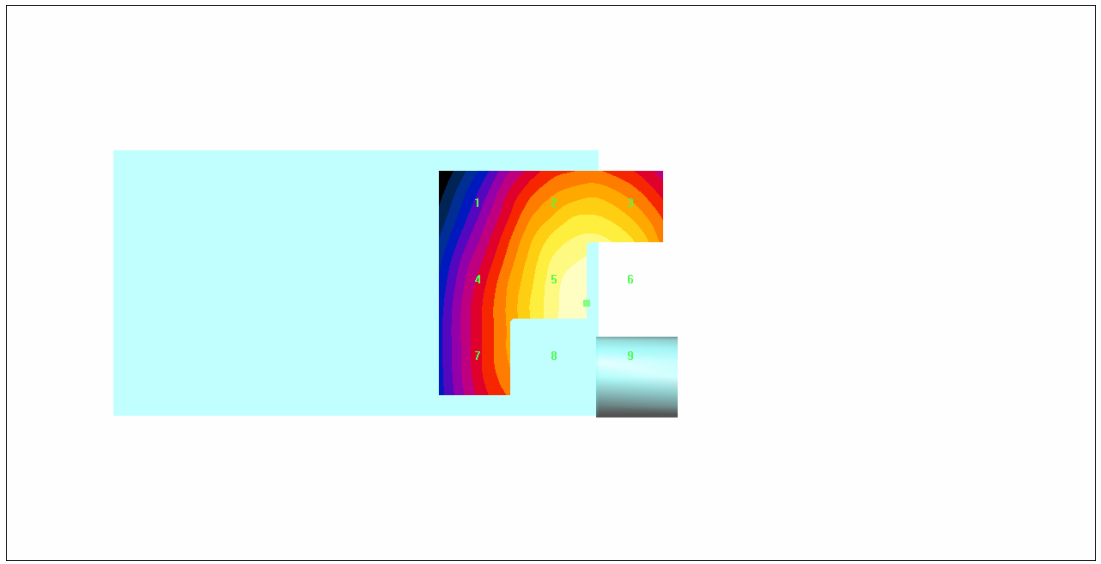
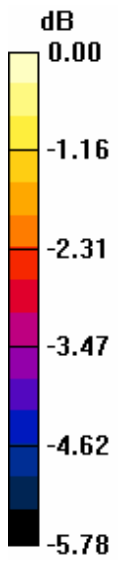
**H Scan - H3DV6 probe center 10mm above Device Reference-High with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.169 A/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.130</b>	Grid 2 <b>0.157</b>	Grid 3 <b>0.157</b>	Grid 1 <b>0.131</b>	Grid 2 <b>0.158</b>	Grid 3 <b>0.158</b>
Grid 4 <b>0.137</b>	Grid 5 <b>0.168</b>	Grid 6 <b>0.168</b>	Grid 4 <b>0.139</b>	Grid 5 <b>0.169</b>	Grid 6 <b>0.169</b>
Grid 7 <b>0.137</b>	Grid 8 <b>0.167</b>	Grid 9 <b>0.167</b>	Grid 7 <b>0.138</b>	Grid 8 <b>0.169</b>	Grid 9 <b>0.169</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.168A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Low/Hearing Aid**

**Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

**Maximum value of Total field (slot averaged) = 0.159 A/m**

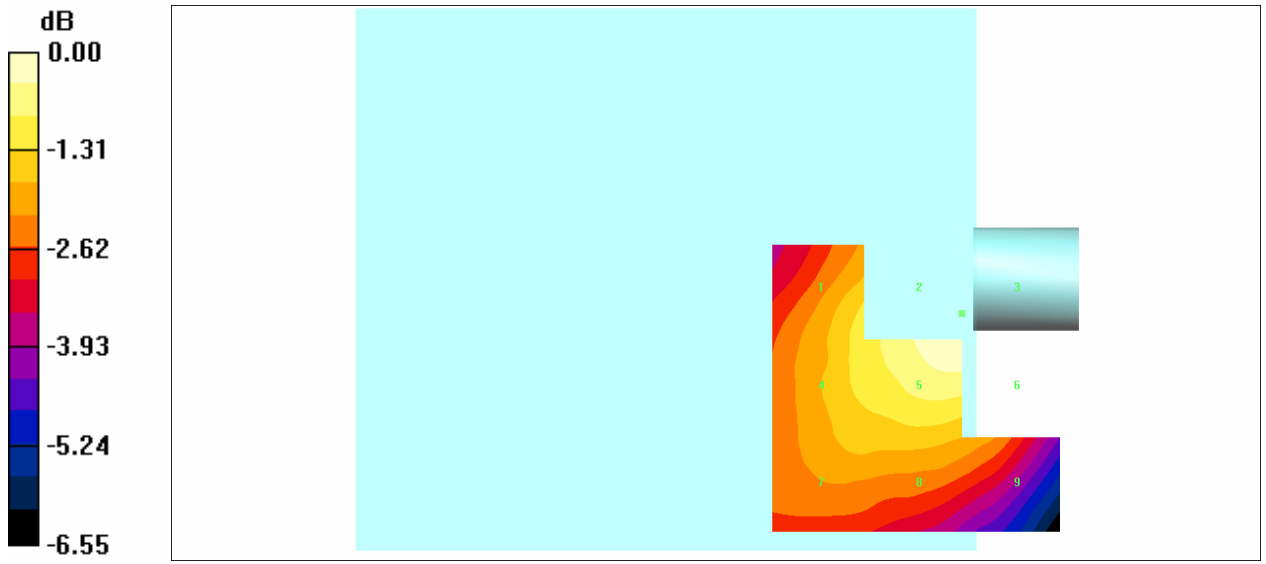
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3
<b>0.141</b>	<b>0.159</b>	<b>0.159</b>
Grid 4	Grid 5	Grid 6
<b>0.141</b>	<b>0.158</b>	<b>0.158</b>
Grid 7	Grid 8	Grid 9
<b>0.133</b>	<b>0.134</b>	<b>0.130</b>

Grid 1	Grid 2	Grid 3
<b>0.142</b>	<b>0.160</b>	<b>0.160</b>
Grid 4	Grid 5	Grid 6
<b>0.142</b>	<b>0.159</b>	<b>0.159</b>
Grid 7	Grid 8	Grid 9
<b>0.134</b>	<b>0.135</b>	<b>0.131</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.159A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

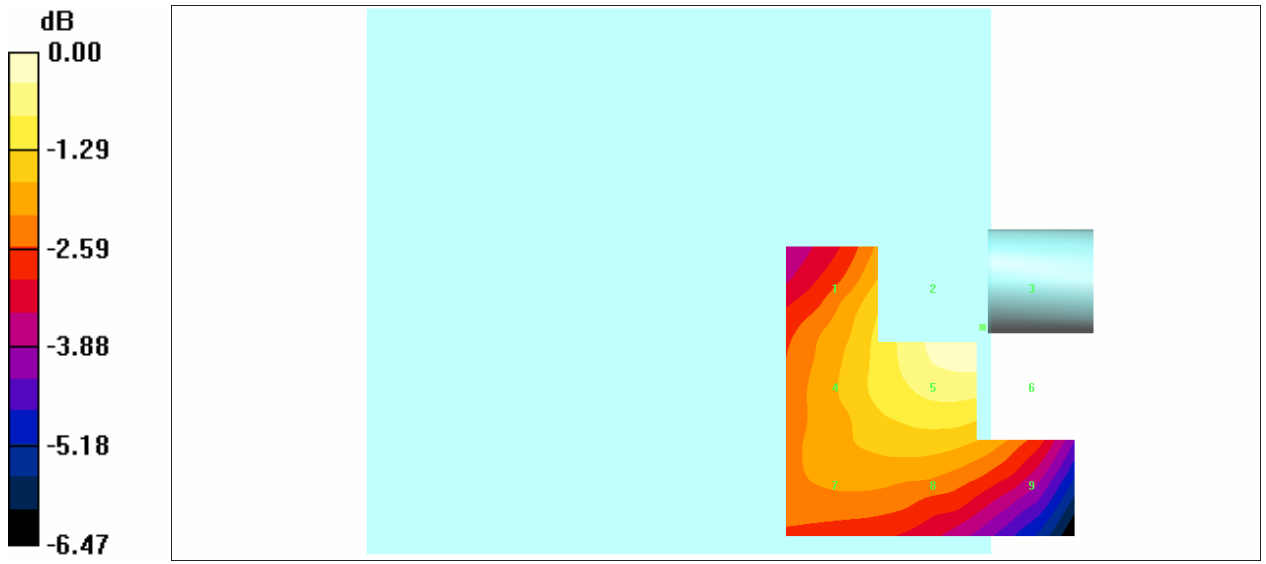
**H Scan - H3DV6 probe center 10mm above Device Reference-Mid/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.160 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.141</b>	Grid 2 <b>0.160</b>	Grid 3 <b>0.161</b>	Grid 1 <b>0.142</b>	Grid 2 <b>0.161</b>	Grid 3 <b>0.162</b>
Grid 4 <b>0.141</b>	Grid 5 <b>0.159</b>	Grid 6 <b>0.159</b>	Grid 4 <b>0.142</b>	Grid 5 <b>0.160</b>	Grid 6 <b>0.160</b>
Grid 7 <b>0.134</b>	Grid 8 <b>0.136</b>	Grid 9 <b>0.132</b>	Grid 7 <b>0.135</b>	Grid 8 <b>0.137</b>	Grid 9 <b>0.133</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 0.161A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

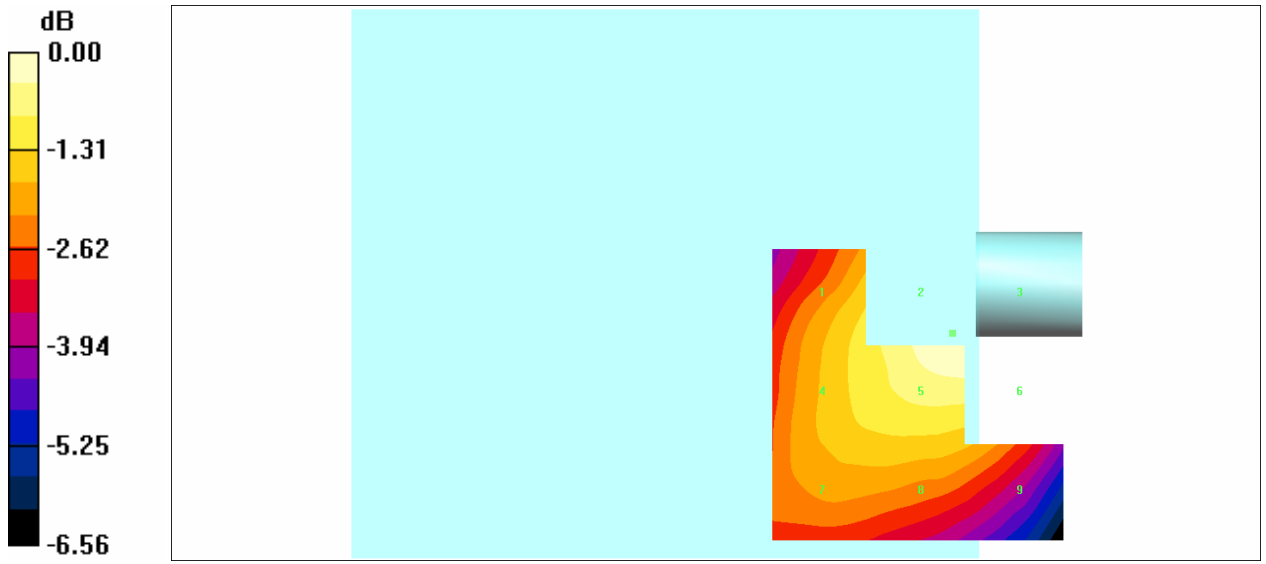
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-High/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.154 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.136</b>	Grid 2 <b>0.154</b>	Grid 3 <b>0.153</b>	Grid 1 <b>0.137</b>	Grid 2 <b>0.155</b>	Grid 3 <b>0.154</b>
Grid 4 <b>0.136</b>	Grid 5 <b>0.153</b>	Grid 6 <b>0.152</b>	Grid 4 <b>0.137</b>	Grid 5 <b>0.154</b>	Grid 6 <b>0.154</b>
Grid 7 <b>0.130</b>	Grid 8 <b>0.131</b>	Grid 9 <b>0.127</b>	Grid 7 <b>0.131</b>	Grid 8 <b>0.132</b>	Grid 9 <b>0.128</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.154A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 824.7 MHz; Duty Cycle: 1:1.015

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DASYS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DASYS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Low with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

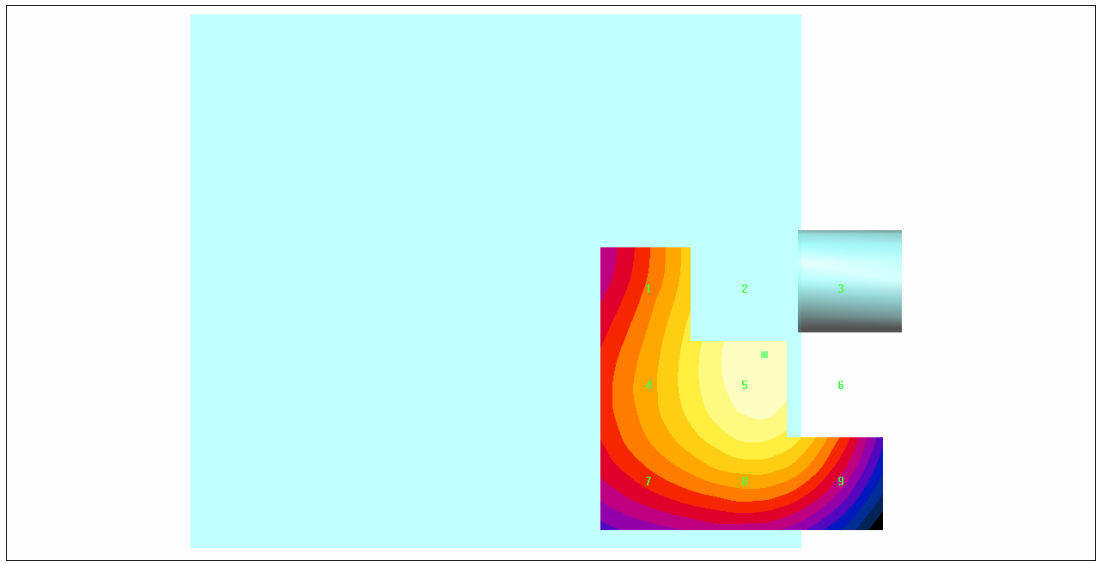
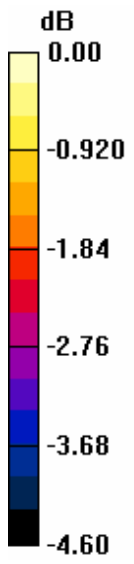
**Maximum value of Total field (slot averaged) = 0.232 A/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
<b>0.211</b>	<b>0.230</b>	<b>0.228</b>	<b>0.212</b>	<b>0.232</b>	<b>0.230</b>
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
<b>0.212</b>	<b>0.231</b>	<b>0.228</b>	<b>0.214</b>	<b>0.232</b>	<b>0.229</b>
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
<b>0.205</b>	<b>0.217</b>	<b>0.212</b>	<b>0.207</b>	<b>0.219</b>	<b>0.214</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.231A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 836.52 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Mid with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

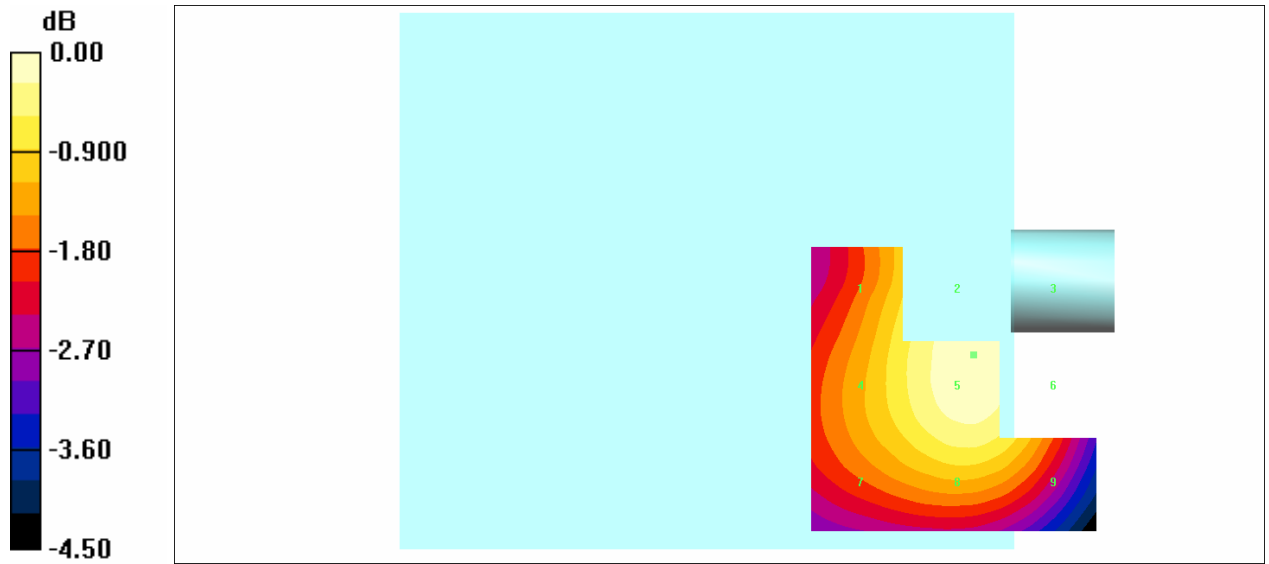
**Maximum value of Total field (slot averaged) = 0.229 A/m**

**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.209</b>	Grid 2 <b>0.227</b>	Grid 3 <b>0.224</b>	Grid 1 <b>0.211</b>	Grid 2 <b>0.228</b>	Grid 3 <b>0.226</b>
Grid 4 <b>0.211</b>	Grid 5 <b>0.227</b>	Grid 6 <b>0.224</b>	Grid 4 <b>0.212</b>	Grid 5 <b>0.229</b>	Grid 6 <b>0.226</b>
Grid 7 <b>0.204</b>	Grid 8 <b>0.216</b>	Grid 9 <b>0.211</b>	Grid 7 <b>0.206</b>	Grid 8 <b>0.217</b>	Grid 9 <b>0.212</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.227A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA835(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: Cellular; Frequency: 848.31 MHz; Duty Cycle: 1:1.015  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

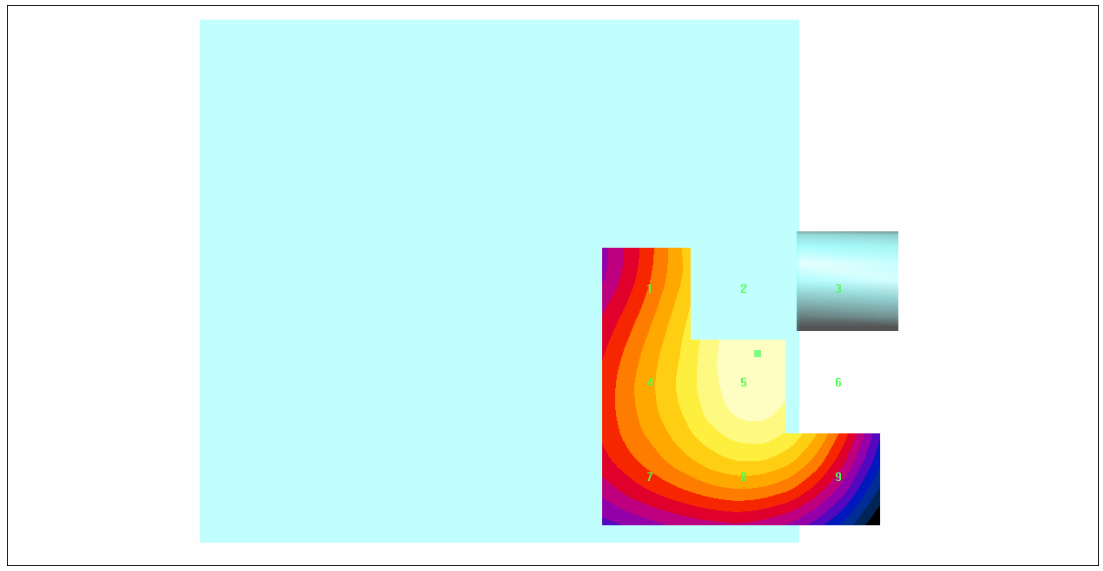
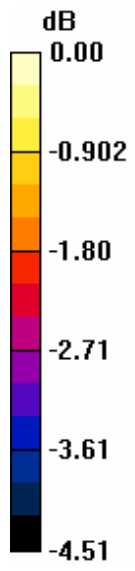
**H Scan - H3DV6 probe center 10mm above Device Reference-High with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.224 A/m**  
**Hearing Aid Near-Field Category: M3 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1	Grid 2	Grid 3	Grid 1	Grid 2	Grid 3
<b>0.203</b>	<b>0.222</b>	<b>0.218</b>	<b>0.205</b>	<b>0.223</b>	<b>0.220</b>
Grid 4	Grid 5	Grid 6	Grid 4	Grid 5	Grid 6
<b>0.205</b>	<b>0.222</b>	<b>0.218</b>	<b>0.207</b>	<b>0.224</b>	<b>0.220</b>
Grid 7	Grid 8	Grid 9	Grid 7	Grid 8	Grid 9
<b>0.200</b>	<b>0.211</b>	<b>0.206</b>	<b>0.201</b>	<b>0.213</b>	<b>0.207</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 0.222A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

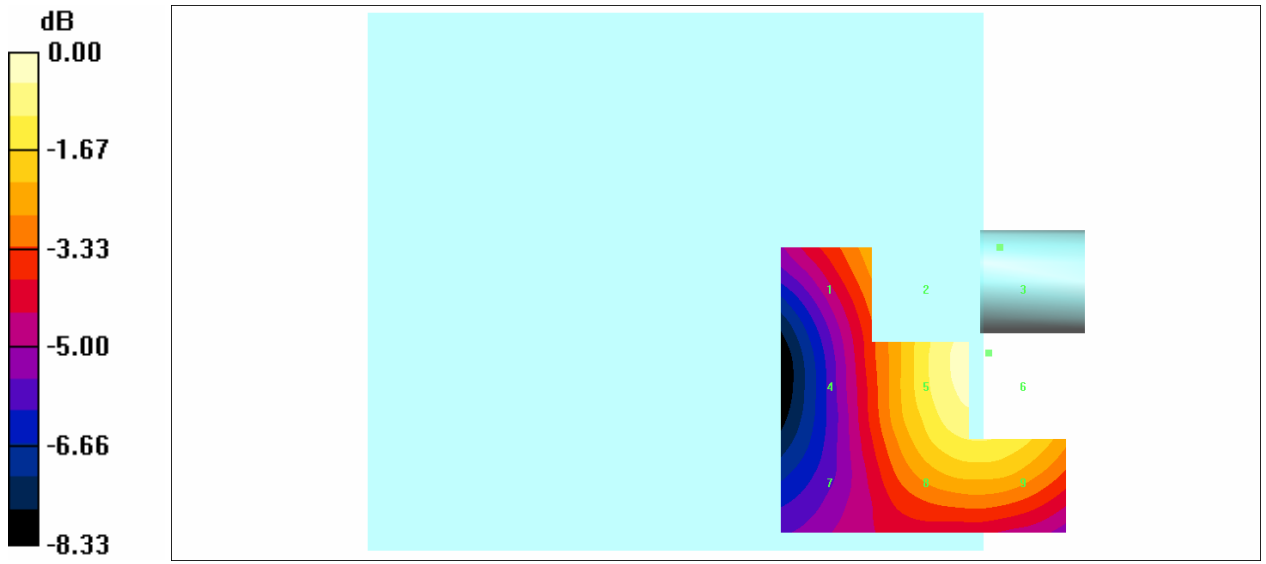
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Low/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.110 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)      H in A/m (Slot averaged)

Grid 1 <b>0.084</b>	Grid 2 <b>0.108</b>	Grid 3 <b>0.111</b>	Grid 1 <b>0.085</b>	Grid 2 <b>0.109</b>	Grid 3 <b>0.112</b>
Grid 4 <b>0.074</b>	Grid 5 <b>0.109</b>	Grid 6 <b>0.111</b>	Grid 4 <b>0.075</b>	Grid 5 <b>0.110</b>	Grid 6 <b>0.112</b>
Grid 7 <b>0.071</b>	Grid 8 <b>0.098</b>	Grid 9 <b>0.098</b>	Grid 7 <b>0.072</b>	Grid 8 <b>0.099</b>	Grid 9 <b>0.099</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.111A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

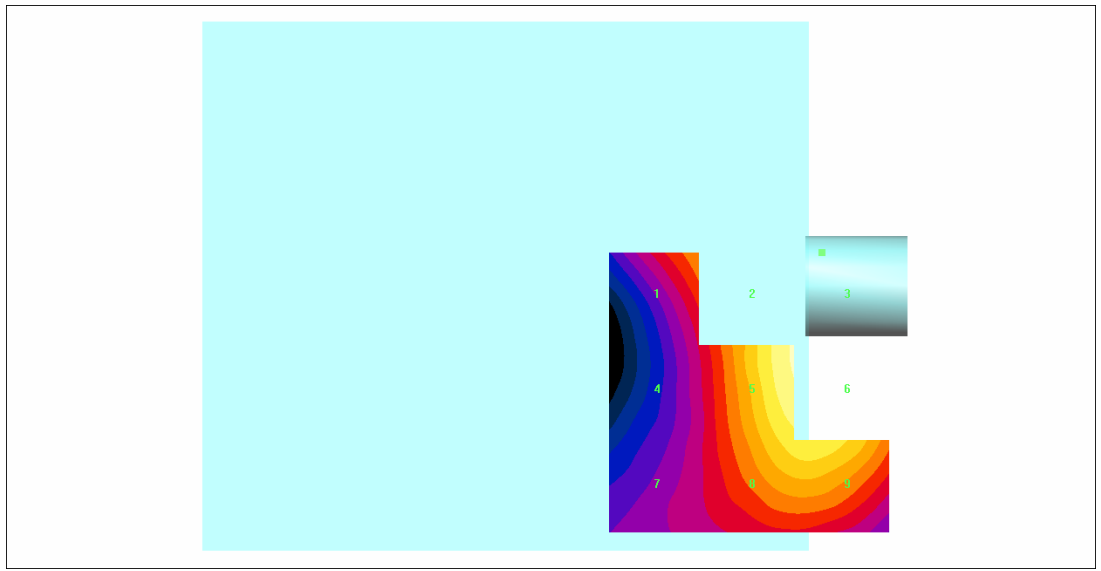
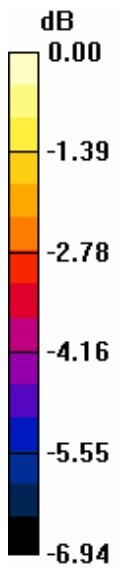
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Mid/Hearing Aid  
 Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm  
 Maximum value of Total field (slot averaged) = 0.107 A/m  
 Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.085</b>	Grid 2 <b>0.108</b>	Grid 3 <b>0.111</b>	Grid 1 <b>0.086</b>	Grid 2 <b>0.109</b>	Grid 3 <b>0.112</b>
Grid 4 <b>0.073</b>	Grid 5 <b>0.106</b>	Grid 6 <b>0.109</b>	Grid 4 <b>0.074</b>	Grid 5 <b>0.107</b>	Grid 6 <b>0.110</b>
Grid 7 <b>0.072</b>	Grid 8 <b>0.098</b>	Grid 9 <b>0.099</b>	Grid 7 <b>0.073</b>	Grid 8 <b>0.099</b>	Grid 9 <b>0.100</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.111A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1.018

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-High/Hearing Aid**

**Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**

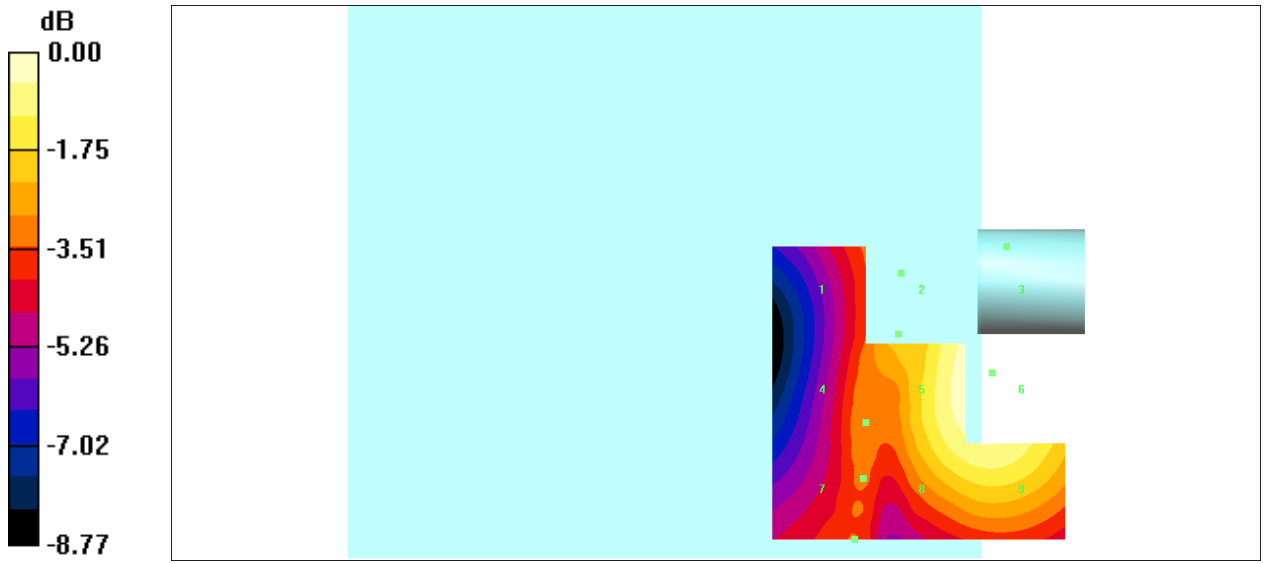
**Maximum value of Total field (slot averaged) = 0.098 A/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.068</b>	Grid 2 <b>0.095</b>	Grid 3 <b>0.099</b>	Grid 1 <b>0.069</b>	Grid 2 <b>0.096</b>	Grid 3 <b>0.100</b>
Grid 4 <b>0.071</b>	Grid 5 <b>0.098</b>	Grid 6 <b>0.100</b>	Grid 4 <b>0.072</b>	Grid 5 <b>0.098</b>	Grid 6 <b>0.101</b>
Grid 7 <b>0.070</b>	Grid 8 <b>0.092</b>	Grid 9 <b>0.094</b>	Grid 7 <b>0.071</b>	Grid 8 <b>0.093</b>	Grid 9 <b>0.095</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.100A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1851.25 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

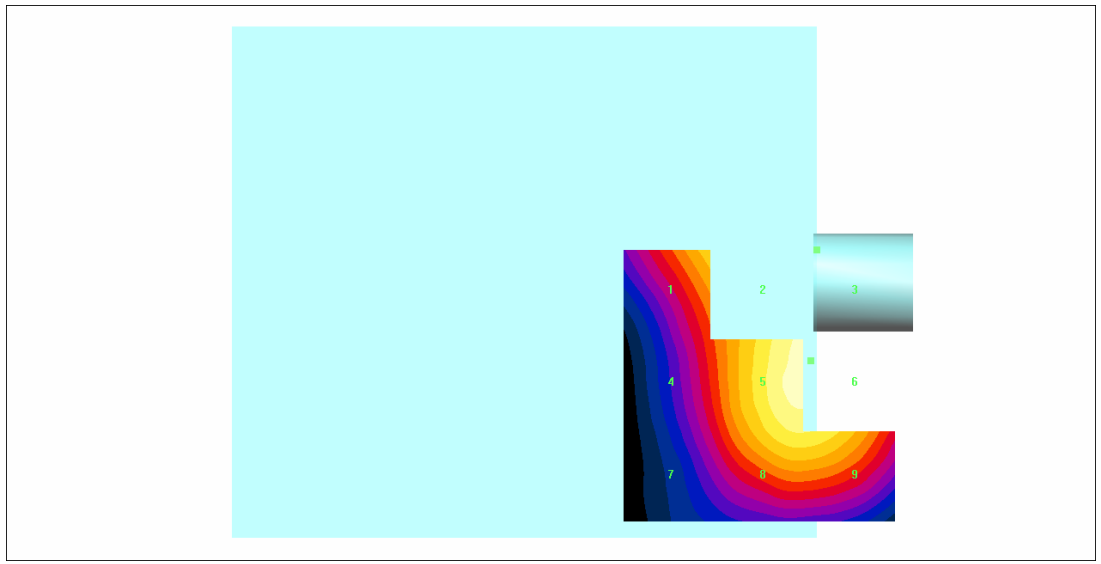
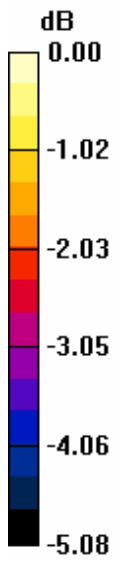
**H Scan - H3DV6 probe center 10mm above Device Reference-Low with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.129 A/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.115</b>	Grid 2 <b>0.129</b>	Grid 3 <b>0.130</b>	Grid 1 <b>0.116</b>	Grid 2 <b>0.130</b>	Grid 3 <b>0.131</b>
Grid 4 <b>0.102</b>	Grid 5 <b>0.127</b>	Grid 6 <b>0.128</b>	Grid 4 <b>0.103</b>	Grid 5 <b>0.129</b>	Grid 6 <b>0.129</b>
Grid 7 <b>0.095</b>	Grid 8 <b>0.121</b>	Grid 9 <b>0.120</b>	Grid 7 <b>0.096</b>	Grid 8 <b>0.122</b>	Grid 9 <b>0.122</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15





0 dB = 0.130A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1880 MHz; Duty Cycle: 1:1.018  
 Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>  
 Phantom section: H Device Section  
 Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

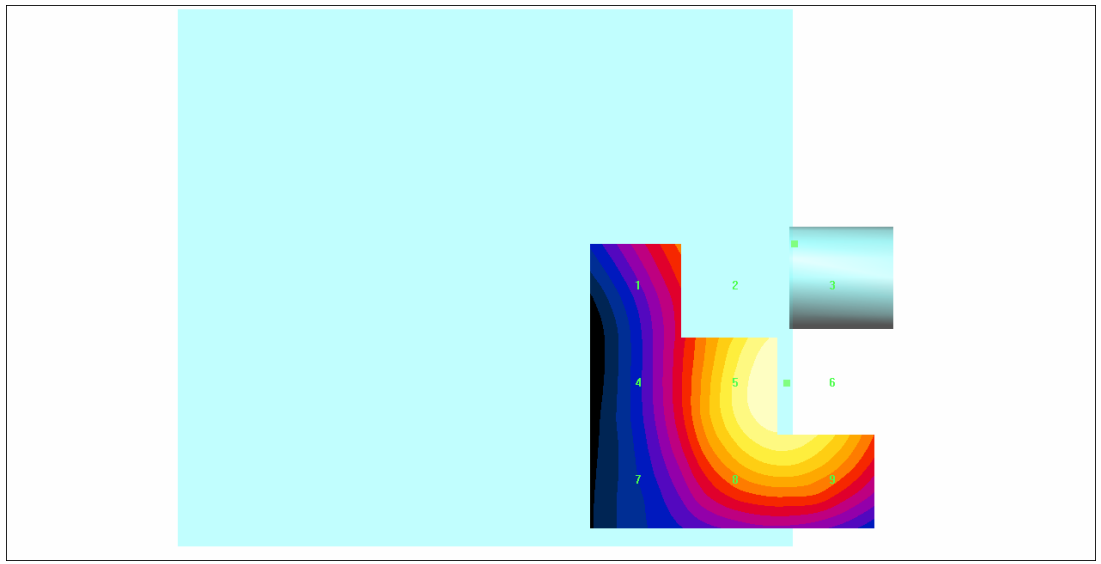
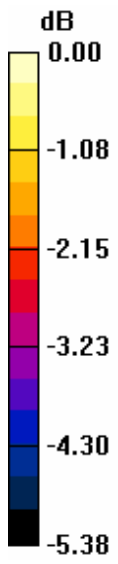
- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

**H Scan - H3DV6 probe center 10mm above Device Reference-Mid with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.130 A/m**  
**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)      H in A/m (Slot averaged)

Grid 1 <b>0.102</b>	Grid 2 <b>0.125</b>	Grid 3 <b>0.125</b>	Grid 1 <b>0.103</b>	Grid 2 <b>0.126</b>	Grid 3 <b>0.126</b>
Grid 4 <b>0.096</b>	Grid 5 <b>0.129</b>	Grid 6 <b>0.129</b>	Grid 4 <b>0.097</b>	Grid 5 <b>0.130</b>	Grid 6 <b>0.131</b>
Grid 7 <b>0.094</b>	Grid 8 <b>0.123</b>	Grid 9 <b>0.123</b>	Grid 7 <b>0.095</b>	Grid 8 <b>0.124</b>	Grid 9 <b>0.125</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.129A/m

Test Laboratory: Compliance Certification Services Inc.

**HAC\_H\_SCAN\_CDMA1900(open)**

**DUT: HTC; Type: PA10A; Serial: N/A**

Communication System: CDMA PCS; Frequency: 1908.75 MHz; Duty Cycle: 1:1.018

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1$  kg/m<sup>3</sup>

Phantom section: H Device Section

Measurement Standard: DAS4 (High Precision Assessment)

DASY4 Configuration:

- Probe: H3DV6 - SN6163; ; Calibrated: 2005/4/27
- Sensor-Surface: (Fix Surface)
- Electronics: DAE3 Sn558; Calibrated: 2004/8/24
- Phantom: HAC Test Arch; Type: SD HAC P01 BA; Serial: 1027
- Measurement SW: DAS4, V4.5 Build 19; Postprocessing SW: SEMCAD, V1.8 Build 146

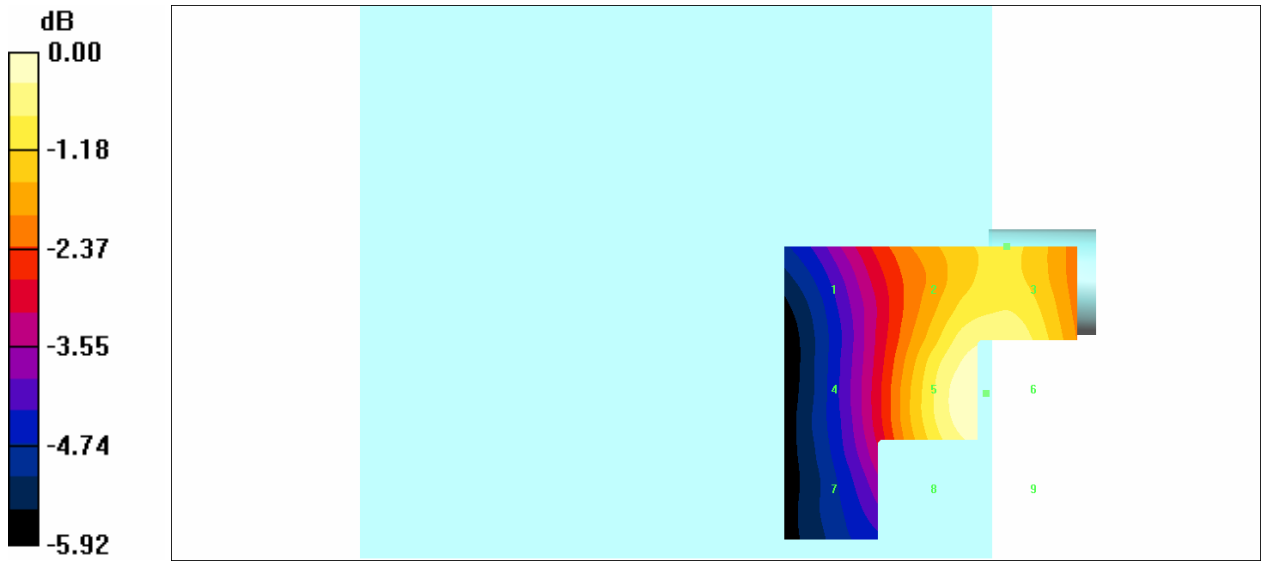
**H Scan - H3DV6 probe center 10mm above Device Reference-High with Co-location/Hearing Aid Compatibility Test (101x101x1): Measurement grid: dx=5mm, dy=5mm**  
**Maximum value of Total field (slot averaged) = 0.133 A/m**

**Hearing Aid Near-Field Category: M4 (AWF 0 dB)**

H in A/m (Time averaged)    H in A/m (Slot averaged)

Grid 1 <b>0.098</b>	Grid 2 <b>0.125</b>	Grid 3 <b>0.126</b>	Grid 1 <b>0.099</b>	Grid 2 <b>0.126</b>	Grid 3 <b>0.127</b>
Grid 4 <b>0.095</b>	Grid 5 <b>0.132</b>	Grid 6 <b>0.132</b>	Grid 4 <b>0.095</b>	Grid 5 <b>0.133</b>	Grid 6 <b>0.134</b>
Grid 7 <b>0.092</b>	Grid 8 <b>0.127</b>	Grid 9 <b>0.127</b>	Grid 7 <b>0.093</b>	Grid 8 <b>0.128</b>	Grid 9 <b>0.128</b>

Category	AWF (dB)	Limits for E-Field Emissions (V/m)	Limits for H-Field Emissions (A/m)
M1	0	199.5 - 354.8	0.6 - 1.07
	-5	149.6 - 266.1	0.45 - 0.8
M2	0	112.2 - 199.5	0.34 - 0.6
	-5	84.1 - 149.6	0.25 - 0.45
M3	0	63.1 - 112.2	0.19 - 0.34
	-5	47.3 - 84.1	0.15 - 0.25
M4	0	<63.1	<0.19
	-5	<47.3	<0.15



0 dB = 0.132A/m